ELECTRONIC REPRESENTATION AND ANALYSIS OF NEURAL TRANSMISSION PROCESS

A DISSERTATION

Submitted in partial fulfilment of the requirements for the award of the degree of MASTER OF ENGINEERING in

ELECTRICAL ENGINEERING (Measurement & Instrumentation)

By

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December, 1985

DEDICATED TO MY PARENTS

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CANDIDATE'S DECLARATION

I hereby certify that the work which is being presented in the thesis entitled, "Electronic Representation and Analysis of Neural Transmission Process", in partial fulfilment of the requirement for the award of the Degree of Master of Engineering in Electrical Engineering (MEASUREMENT & INSTRUMENTATION), submitted in the Department of Electrical Engineering of the University is an autbentic record of my own work carried out during a period from August, 1984 to November, 1985 under the supervision of Dr D S Chittore.

The matter embodied in this thesis has not been submitted by me for the award of any other degree.

Candidate Signature (ANIL KUMAR GARG)

This is to certify that the above statement made by the cancidate is correct to the best of my knowledge.

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ROORKEE

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CHAPTER - I

INTRODUCTION

Rodelling of biological systems help in getting a clear and consistent picture of its working and various processes. It can be used to verify experimentally known relationships and to establish new relationships. The models are similar in function but different in structure from the original biological systems.

In most of the cases the models are predictive and it is possible to diduce some some characteristics of the system. Nodel also suggests the constraints existing in the system being modelled. Thus the model reveals, computes, extrapolates and predicts the new facts which accelerates the process of learning about the actual nervous system.

Models could be of various types such as mathematical, chemical, electrical, electronics etc. [1] Every type of modelling techniques has some advantages and disadvantages and their selection depends upon requirements and objectives. Biological systems usually require complex equations for representations in mathematical format. Chemical models require large space, more cost and also are not convenient in varying its parameters for observing their effects on overall systems or a part of the system. The electrical/electronic models are small in size, less costly and convenient in handling. Any type of nonlinearity can be included with reasonable accuracy.

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Interest in the climical application of peripheral and central electrical stimulation of nerves is growing rapidly. Thousands of patients are now being treated for chronic pain.

Using both superficial and inplanted electrode Glenn (4) have developed on electrophremic respirator which have been implanted in nearly thousands of the patients with inadequate or no respiratory function. Waters have reported (5) on a series of stroke wistins in which paralysed numbers of the leg are activated electrically during ambulation to improve walking. Experimental work is under way (5) to develop neuroelectric prostheses for the deaf and blind. As these clinical efforts multiply, it becomes imperative that an electrical model of nerve system is made available to provide an analytical and experimental foundation for the study of electrical eignal propagation and nerve excitation,

Namy physical systems are linked to norve system and therefore many attempts have been made to model the nerve obaracteristics from last two conturies. (2) Neural system modelling may be expected to exert increasing influence on the gourse of neurophysiological research.

The selection of parameters in neural modelling has two distinct philosophies.

- (a) A very lagge number of neural properties of actual neuron are reproduced with high accuragies.
- (b) A more restricted set of properties is used but the restrictions have been made on the basis of a priori set of assumptions with regard to the significant one.

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Hodels of first type are more complete but more difficult to realise and are more costly. Hodels of second type are more amenable to analysis but are in great danger of important ommissions.

Once a model of neural system has been realised, there are three types of actions which are to be taken. The first, which is mandatory consists of preliminary validation by testing meural models performance with actual physiological behvariour of the neural system. Successive refinements of the model may then lend to convergence to an accurate and revealing abstraction. Second, after the validity is tentatively established it could be attempted to discover new properties of the model, i.e. the operations not explicitly considered in the original design. Although such discovered properties are implicit owing to the choice of parameters of the circuit, it is likely that all of them will have been foremeen. Another use of the model is that it can test hypothesis and explore then direct physiological measurement on the actual neuron.

1.1 <u>ORGANISATION OF PRESENT WORK</u>:- This work deals with analysis and modelling of actual neural system for its important electrical characteratics. An electronic model of neuron with a local feet back has been developed which has capacity to show equivalent electrical properties.

The second chapter deals with the discussion on enatomical and physiological aspects of the neuron. It deals

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the analysis of the nerve cell or neurom which is the basic functional unit of the nervous system. Anatomy of neuron is followed by the analysis of the processes occuring inside this unit. All the important electrical characteratics of the neurons are analysed and discussed which form the basis for the development of the neuron model.

The third chapter presents uptodate review of the existing models of the meural system and the research work in this field.

The fourth chapter deals with a new model of the neuron with a local feed back which has been developed by the another. The improvement in this model over existing models are also given. The model is constructed and tested for all the important electrical characteratic of the neuron. The model is tested for stendy state and transient conditions.

The fifth chapter summerizes general conclusions about the existing models and also about the new model. Some suggestions are also given for the further work in this field.

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CHAPTER 2

ANATONY AND PHYSICLOGY OF NEURAL SYSPEN

2.1 INTRODUCTION:

The nerveus system of multicellular organism is typically composed of neurons or nerve cells [2]. Heuron is an elementary unit of nervous system which serves to sense and transmit the information in an electrical form from central nervous system to different parts of the body and vice-versa. These may be arranged in a simple or in complex arrays. When a particular part of body is excited the information is carried in either direction with characteristic velocity [1, 4] e.g. if a finger is suddenly exposed to thermal shock, the information reaches to the brain through the neural network and reaction of the brain is transmitted back through the neurons to the finger muscles for further necessary sotion (say to remove the finger from the source of heat). There is mothing inhercent in assures which governe the direction of information in it; that is, the same neuron work as sensory as well as motoneuron [1].

The information flow is essentially an electrical phenomenon as has been evidenced by experimental facts [2]. These are some 10¹⁰ neurons [2] in the human Central Mervous System (CHS) consisting of brain and spinal cord.

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The Central Fervous System is most important part of the human transmission system. It consists of the following parts [34]:-

- 1. Herve della
- 2. Glial cells
- 3. Blood Yessels
- 4. Cerebraspinal fluid

2.2 ANATONY OF STUROSSI

The human Central Hervous System contains a complicated network of perhaps ten billion highly specialized cells called neurons, or nerve cells [2]. Although no two neurons have exactly the same structure, fortunately they do share certain features [2] that are significant for the neurophaiologist. Like other cells, the neuron is supported by a thin membrane (the plasma membrane) and has a cell body or equivalent some. Projecting from the some are a number of extensions of the cell known as the dendrites and the aron. Figure 2.1 shows the important parts of the cell. Generally a single axon arises from the some, but, as shown in the figure, this aron may give off side branches and characteristically divide into a number of smaller branches, just before terminating. Several dendrites arise from the call body and then branch again and again to form a complicated tree like structure known as the dendritic tree. Two neurons are interconnected through a Renshaw Cell. The dimensions of a neuron very greatly from one to the next. Generally the dell body is roughly 30 micron across (1 micron = 10^{-6} meter), and dendrite

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so much so that the sometic and dendritic membranes are literally encrusted with synaptic endings [2], on the other hand, a synapse between two axons is less frequently observed [2] although such axo-axonal synapses do occur.

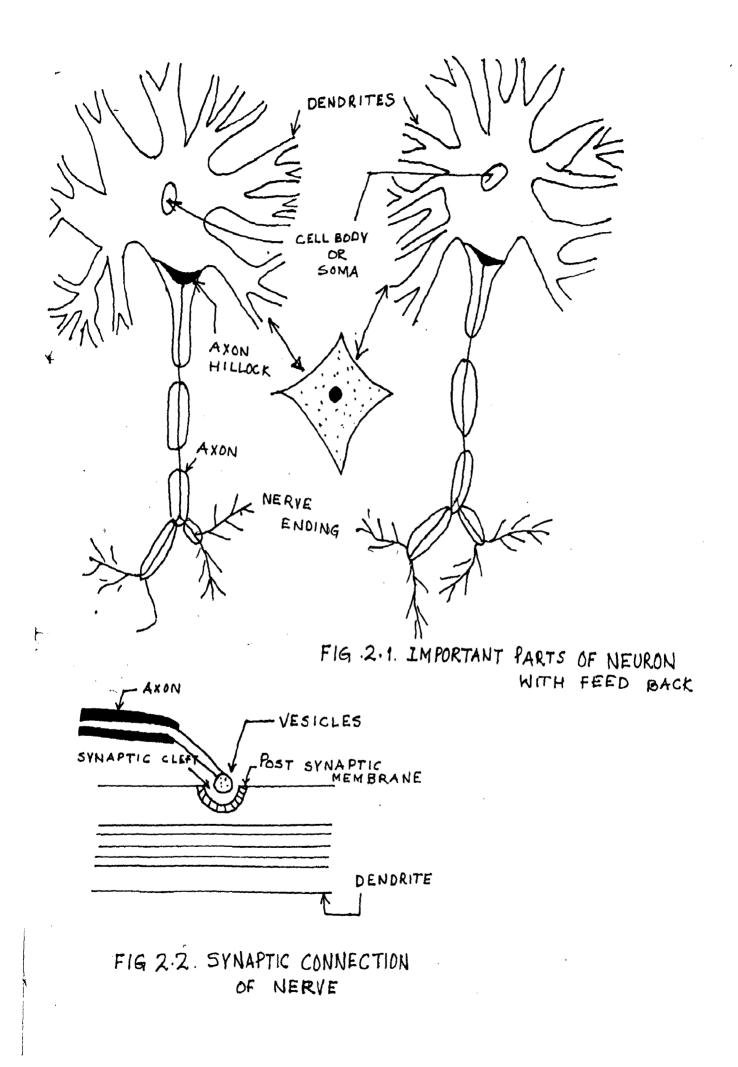
The synappe is of such central importance that it will be useful to have a more detailed picture of structural features shared by the more common types of synapse. Figure 2.2 shows a schematic gross section through a segment of dendrites and several of the numerous aron terminals which make contact with the dendrites. A narrow space about 200 to 300 "A wide (1" A=10¹⁰ meter or $t\bar{0}^{14}$ micron) [3, 4] separates the presynaptic membrane (the axon terminal adjacent to the dendrites) from the post-synaptic membrane (dendritic part of the synapse); this space is known as the synaptic cleft. On the presynaptic side are found a number of mitochondria, indicating that the region is metabolically active. Although mitochondria are found in cells of all types. there is a completious structre which is characteristic of synapses, the synaptic vessel. Synaptic veshel as seen with the electron microscope are dircular in cross section, 300 to 600"A in disseter, and are nearly slowys found in numbers adjacent to the presynaptic membrane.

A neuron receives informations through synapses located on its deadrites and some, integrates this information in its some, and finally transmit the information ever its axon to other dells. The accuracy of the CNS control over the sotivity of the various organs is due to the existance of a two way circular connection between nerve centres & the peripheral organs [4]. are 200 to 300 micron long. It is the length of the amon which is subjected to the greatest variation from one nerve cell to the mext, for among may be from perhaps 50 micron to several meters long [2].

Nerve cells are not isolated but rather are inter connected in a very characteristic way. A bundle of nerve is called a trunk. A trunk includes a wide range of exon sizes. Dismoter of fibres ranges between 0.5 to 1.5 micron [2]. The conduction speed for typical fibers is 1.73 x 10⁶ diameter/sec [2, 3] indicating the speed between 0.5 and 2.3 m/sec [2]. The same trunk carries afferant (toward the brain) fibers from sensory receptors and efforent (avey from the brain) fibers to suscles. The largest fibers are syclinated. Hydinated sheath is a relatively thick layer of fatty substances, myelin etc. The valls of the unmyelinated fibers also consists of fatty molecules but these are not visible because they are very thin (100"A wide) [2, 4]. Special points of contact between neurons called synapses, are of particular importance, for it is at the synapse that information flews from one nerve cell to the next. Typically, the aron of one nerve cell forms a synapse with (or synapses with) either the cell body or dendrites of other neurons. Thus there are two principle types of synapses, aro-dendritic (aron with dendrite) and axo-somatic (axon with cell body). In fact, it has been discovered in recent years that virtually all of the surface of a neurons some and dendrites are provided with axon terminals,

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Because neurons have synsptic connections with one another, they form neural circuits, and it is the property of these circuits that determine the behaviour of the nervous system and thus of the organism.

Although the brain is complicated, fortunately it is not obaotic despite individual variations. In general, it is possible to distinguish particular brain areas where cell bodies and dendritic trees are concentrated (such areas are called nuclei) and other regions which consists primerily of axons running from one group of neurons to another. In these later region large numbers of closely packed axons run in parallel to form structures called tracts (or fibre tracts) fiber here refers to axon or nerve fibre. Similar tracts also run outside of the brain (for example, to muscles), in which case they are referred to as herves. Cell bodies are grouped to form nuclei. A single nucleus might contains thousands of neuron cell bodies.

Thus the neuron consists of --

- (i) Cell body or some
- (ii) Processes
 - (a) Dendrites
 - ()) Aron-Hillock & Aron

2.2.1 CKLL BODY OR SOMA:

The gell bodies of neurons are concentrated in the gray matter of the corebral hemispheres, the subcortical formations, The brain stem, corebellum and spiral cord. The cell body of a seuron contains a well defined nucleus and nucleons. Within the cytoplasm are small macases of a deep standing material called Missl substance. This

The neuron some is contained within a thin wall similar to that of an unmyelinated fibre. It receives the input from the dendritic network. The motomeuron somes are physically located in the spiral cord, topologically opposite the muscles they direct. Some responds to the algebraic summation of incoming message [2].

The some regulate their metabolism and nutrition. As a result the separation of an axon from the body of the nerve cell leads to degeneration of its processes. Gell bodies vary considerably in size, roughly from 5 to 50 microns in diameter. They are a vital part of the neuron. If, as a result of mechanical injury or disease, the cell body is unable to survive, then the processes size die and are unable to carry nervous impulses. Paralysis of suscles follows if injury to neurons prevents nervous impulses from reaching the subcles.

2.2.2 DENDRITES

The projected part from cell body is known dendrites. Each dendrite branches again and again to form complicated tree like structure as shown in Figure 2.1. The dendrites have certain properties which specialize then for receiving the information transmitted along the aron; similar to the one which originally generated the azonal nerve impulses. The dendrites integrate the information contained in arriving nerve impulses.

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After a merve impulse arrives at an axon terminal, there is a brief delay of about a half millisecond known as symmptic delay followed by a characteristic fluctuation of the demoritic membrane potential. This fluctuation is known as the postsymmptic potential or PSP. The typical PSP has a rapid rise to a peak followed by a much longer (approx. exponential) return to the besting potential.

There are two differences [2] between PSPs and motion potentials.

(1) PSPs time duration is larger than an action potential.

(11) Much smaller in amplitude.

The arriving nerve impulse causes the release of a small quantity of a chemical, generally known as a transmitter substance, which diffuse across synaptic cleft and results in the demáritic electrical response.

There are two important properties of dendrites. I. <u>GRADED RESPONSIVENESS</u>:- It refers to the fact that the size of a PSP is proportional to the amount of transmitter released and is to be contrasted with the thresold and all or none behavious characteristic of the axon Figure 2.6.

II. TEMPORAL SUMMATION:

Dendritee, in contrast to the axon, shows no refractory period, "period during which second spike can not arise till the response of the first impulse is not completed". Figure 2.7 shows that two PSP securing in rapid auccession are seen to sum. This important property, that a new PSP simply adds to what remains of all proceedings PSPs is referred to a temporal summation, if at a particular synapse, nerve impulse begin to arrive with a constant frequenty, each resulting PSP will add to the reminder of all proceeding an an increasing depblarisation will occur as the PSPs sum. Bather than increasing indefinitely, the depolarisation will level off at an average value proportional to the frequency at which the nerve impulses are arriving as shown in Figure 2.8.

Since the depolarization of the neuron results in the production of nerve impulses, the depolarizing PSP is termed as excitatory post-synaptic potential (EPSP).

The hyperpelarizing PSP is known as an inhibitory post-synaptic potential (or IPSP) because it opposes the action of MPSPs and tends to prevent the generation of action potentials.

The period in which the spike appears and develops correspond to the complete lack of excitability. It is known as the absolute refractory period [4] when another spikes cannot be evolved by a second stimulue, however strong i.e. the minimum period during which it is impossible to evoke a second action potential is known as absolute refractory period. In the quick conducting fibres of warm blooded animals its value is about 0.5 milli-second.

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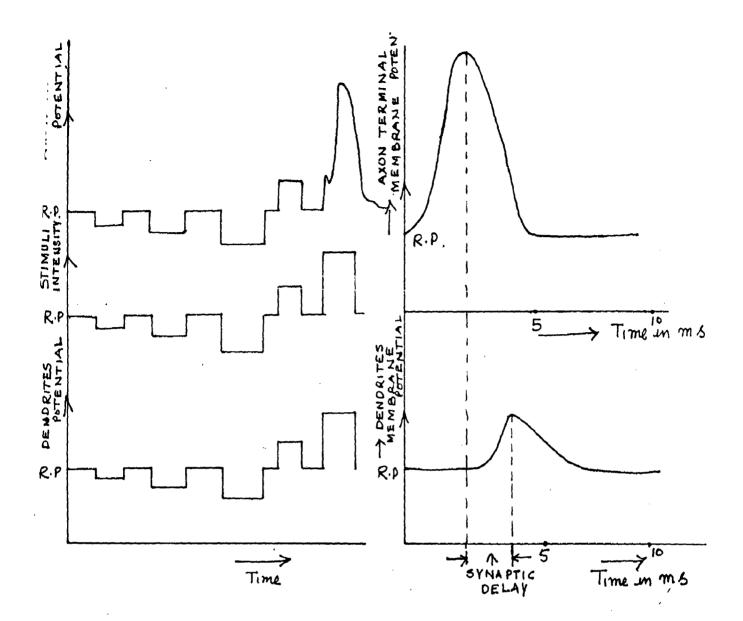
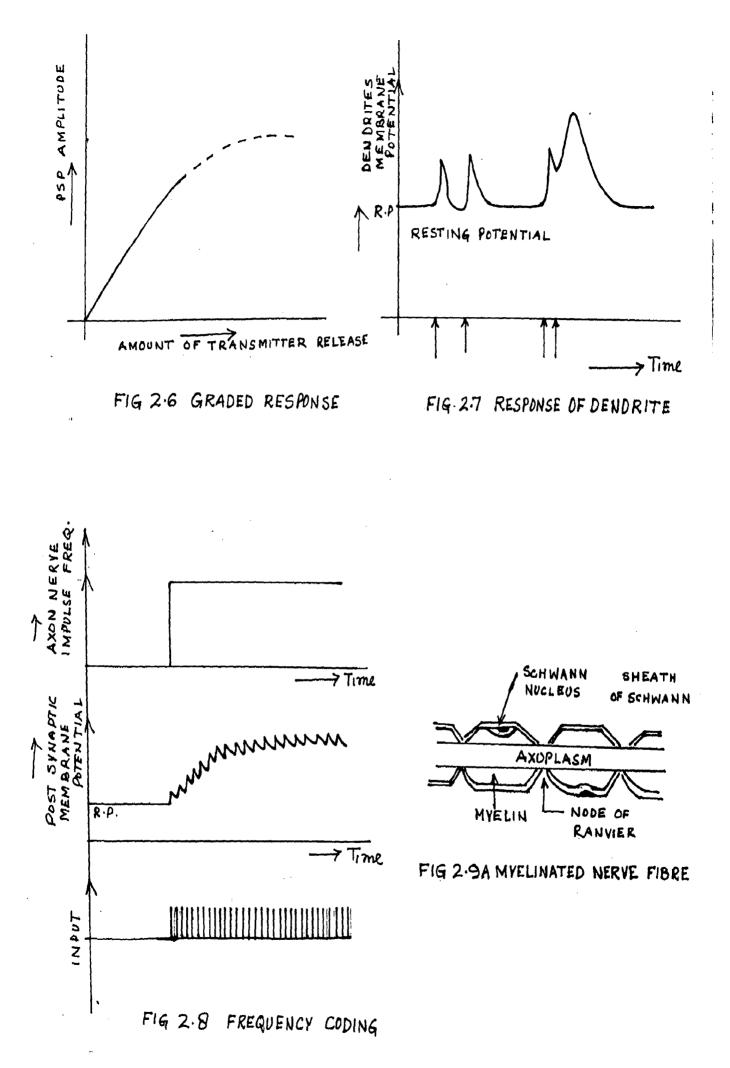


FIG 2.4 RESPONSE OF DENDRITE & AXON WITH AMPLITUDE OF INPUT PULSE

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FIG 2.5. RESPONSE WITH ABOVE THRESHOLD STIMULI



The absolute refractory period is followed by relative refractory phase which lasts for 4 to 8 millimsecond [4] in nerve fibres during which the excitability gradually reverts to the initial level prevailing before the first stimulation. In the refractory period which fibre is capable to respond to a strong stimulus but the amplitude of the sotion potential is much reduced. The amplitude of spike induced by second stimulus increases only when the interval between consecutive stimuli lengthened.

2.2.3 AXON AND ARON-HILLOCK:

The axon is a process that fonduots an inpulse sway from the cell body to other cells or to peripheral organs, it is extended from cell body. The area of the cell from which the axon arises is the axon hillock. Over the first 50 to 100 microms of its length the axon has no medullary sheath and that portion with the hillock before the axon becomes covered by the myolin sheath is the initial segment. The special features of this megnent is its high emoitability. Its stimulus threshold is one-third of that of other parts of the neuron [1, 2]. The axon of the neuron may be very short, as in association neurons (Golgi type XI) or it may be two or three feet long, such as those extending from the grey matter to the spinal cord to the muscles of the fingers or toes. Arons terminate in fine branches celled terminal filaments or telodendria. The tips of these terminal branches appear to be highly specialized to

provide the transmission of the merve impulse to succeeding neurons or to a muscle effector. The difference between axom and dendrite is based primarily not on minor differences in structure but on difference in function. The nerve impulse conducted over a series of neurons passes from the axon and terminal filament of on neuron by synaptic transmission to the dendrites and cell body of the succeeding neuron.

The information is transmitted in the form of frequency or the number of impulses per second travelling along the axon. There are two properties of axons which give rise to nerve impulse and to the coding of information [2].

The inside-outside voltage difference across the axon's membrane is referred to as a membrane potential. In the new terminology, the presence of nerve impulse is signalled by a fluctuation in membrane potential. The value of the membrane potential when the axon is at rest, that is, when no nerve impulses are occuring is known as resting membrane potential or simply resting potential. The value of resting potential is same at different locations of the axon. Typical value of resting potential is -60 m.V, so resting potential provide a reference point.

Whenever the membrane potential is more positive than the resting potential, that is, whenever the inside-outside voltage difference: is less than -60 mV, the axon is said to be depolarized. If however, the membrane potential is below

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the resting value (i.e. about -80 mV), that is more negative than -60 mV, the aron is said to be hyper-polarised. Finally any change which decreases the inside-outside potential difference is known as a depolarisation whereas an increase in the membrane potential is called as hyper polarisation. Aron is normally polarised, that is, has a resting potential and alteration in membrane potential which diminish this resting polarisation are depolarisations, whereas those acting to increase the polarization are hyper polarizations.

The dendrites, like all parts of the nerve cell including the axon has a resting potential of approximately -60 mV, this resting potential is constant over the length of dendrites and, indeed, over the entire neuron. The dendrites and axons have the same response to hyperpolarising stimuli. In both cases, the response mirrors the stimuli with a slight distortion. The axon response to small depolarization is passive being always a mirror image of the response to hyperpolarization of similar magnitude. The property is also shared by dendrites. In summary, dendrites have all of the passive electrical properties of axons as shown in Figure 2.4.

The distinctive property of the axon is its active response to above threshold depelarisation known as the action potential. But the dendrites do not respond to depolarisation, as do axons, by producing action potentials, but rather slow only passive responses to both depolarizing and hyperpolarizing stimuli of all magnitude as shown in Figure 2.5.

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The magnitude of dendritic depolarization is opreximitely proportional to transmitter concentration. When a nerve impulse arrives at the synapse, a small amount of transmitter is released and diffuse across the 200°A or 300°A synaptic eleft to the dendritic membrane. The transmitter concentration at the dendritic membrane increases very rapidly to a peak. Thus dendritic depolarization increases very rapidly and returns slowly to the resting potential, thus producing the PSP.

2.2.4 SYNAPSES IN THE CHB.

Special points of contact between neurons, called synapses, are of particular importance, for it is at the synapse that information flows from one nerve cell to the next. Synapses located on the body (Some) of a neuron are called and smattic and those on the dendrities are called and dendritic. As pointed out earlier a synapse in the CMS, consists of three principal elements [1, 2] as shown in Figure 2.2.

- (1) Presynaptic membrane
- (11) Post-synaptic membrane
- (111) Symmetic cleft

(1) <u>PER-STRAPTIC REMBRANE</u>:

Norve ending in the CHS wary in shape, generally looking like knobs; each synaptic knob is covered with a membrane, the so called pre-synaptic membrane [1, 2]. It is the axon terminal adjacent to the dendritte. Norve calls are not isolated rather

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inter-connected in a very characteristic way. Fre-symmittic membrane covers the nerve ending. The nerve ending is a peculiar neurosecretary apparatus, which secrets the mediator that produces a stimulating excitatory or inhibitory effect on the innervated Cell. [4]. The mediatrons are highly active chemical compounds.

(11) POST-SINAPTIC MEMBRANE:

It is the dendritic part of the synapse. The portion of the membrane of the innervated cell directly adjoining the nerve ending is known as the post synaptic membrane. The post synaptic membrane differs in its properties from the membrane covering the remainder of the cell, the chief difference being that it possesses very high chemical sensitivity to the mediator and is insensitive to an electric current $\{1, 2\}$.

(111) SIBAPTIC CLEPT:

A narrow space about 200 to 300°A wide ($f^*A = 10^{10}$ metre) separates the pre-synaptic membrane (the axon terminal adjacent to the dendrite) from the post synaptic membrane (dendritic part of the synapse); this space is known as the synaptic oleft.

Because neurons have symmptic connections with one another, they form neural circuits, and it is the properties of these circuits that determine the behaviour of the nervous system and thus of organism.

2.2.5 UFEYELIMATED ANONS

It resembles a tube that is filled with a weak solution mostly of potassium ions (X^+) . The fibre is surrounded by the interstitial fluid of the body essential a Ma⁺ Cl⁻⁻ solution.

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Total internal and external concentrations are about the same. The diameter of the fibres ranges between 0.3 and 1.3 micron [1]. The conduction speed for typical fibres is 1.73 x 10⁶ times diameter per second indicating speed between 0.5 and 2.3 m/sec [1].

The difference between internal and external concentration and temperature are maintained by metabolic activity. The inside of the fibre at rest displays a potential of $\tau = -70$ mV with respect to the outside. This corresponds to an electric field within the membrane of 70 mV/100°A = 70000 V/Cm. By way of comparison the dislectric strength of insulating oil is about 10000 V/Cm [f]. It turn out that the fibre signal is a spike that is accompanied by break-down of the membrane. This breakdown, in fact, regenerates the signal. The fibre operates with a threshold of about -SOnV, when the inside at any point becomes nore positive than this value; the break down is triggered. The membrane becomes permeable to sodium ions for about 2 milli second, as the ione enter the fibre, the voltage increases to approximately +30mV. After about 2 milli second internal, there is an additional 2 milli second refractory period (interval) during which the membrane becomes a relatively good insulator again. Because the disturbance is 4 milli second wide, the maximum possible frequency is 250 Hs. The excess sodium ions that lasked in are slowly and more or less continuously pumped out with energy supplied by the metabolic activity. The -TONY resting membrane potential [1] may be regarded as a d.c. component that is super-imposed on the 100 mV peak spike known as an action potential that actually constitutes the aron signal.

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In unsychinated aron the action potential sweeps continuously along the axon, the action potential from one small segment of axon spreads passively to the adjacent segment where it acts as a stimulua to produce another action potential. This process is repeated for entire length of axon [2].

2.2.6 MYRLINATED AXON:

The myelin sheath at a regular interval of 1 to 2.5mm is periodically interruped by the nodes of Ranivier [1, 4] as shown in Figure 2.9. It is at these modes that the action potential is regenerated in the usual way by an inward diffusion of sodium ions between one node and the next. The fibre behaves like a passive RC cable that is if a 100 mV spike originate at a particular node [4], it will appear at the next node with increased width and reduced height. The height is mormally sufficient to overcome the threshold requirement of 20 mV peak, so that regeneration takes place. Fibre external diameter range from 1 to 22 microns [2]. In contrast to the unsyslinated structure in which the membrane thickness remains constant of 100°A. The myelin thickness if approximately proportional to fibre diameter. The conduction speed is about 10 times (i.e. 120 m/sec) than that of unsyslinated aron [2].

Large merve fibres are sharafterised by the fact that they are surrounded by a myslin sheath of mainly lipsid material as shown in Figure 2.9A. The myslin sheath in turn is surrounded by a specialised §mbe of cell called the Schwann Cell. According to present concepts, the myslim sheath actually consists of many

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layers of schwann cell membrane which more left behind as the cell body rotated around the axon during growth. The model region is characterised by its low electrical resistance. This geometry imparts certain constraints on conduction in myelinated axons.

The plasma membrane surrounding a neuron can be investigated by using electron microscopy and X.rsy differaction methods. Additional information on the properties of the membrane has been deducted from permeability, electrical conductivity and surface tension measurements.

The presence of syclis sheath around large arous tend to alter the mode of propagation in this type of fibre [1].

To sheath which may be composed of a considerable number of tight turns of 120°A thick lamins [1, 2] has low electrical conductivity and functions much as insulating material on a metallic wire. The node of ranvier is covered only by schwann cell tyteplaam and form a functional point of view, the axon plasma membrane is bare at the node. Activation in the myelinated axons, therefore, occurs at a nodal region and produces a local circuit current which completes the closed loop via adjacent nodes. As current flow is constrained primarily to nodal area, current density is relatively high at these circumscribed sites. For this reason, the activation jumps from node to node, and this phenomenna is called saltatory conduction. Hyelinated perties of the axon does not give action potential when depolarised. Thus the action potential moves along the axon by yassive spread in the myelinated regions and by the occurence

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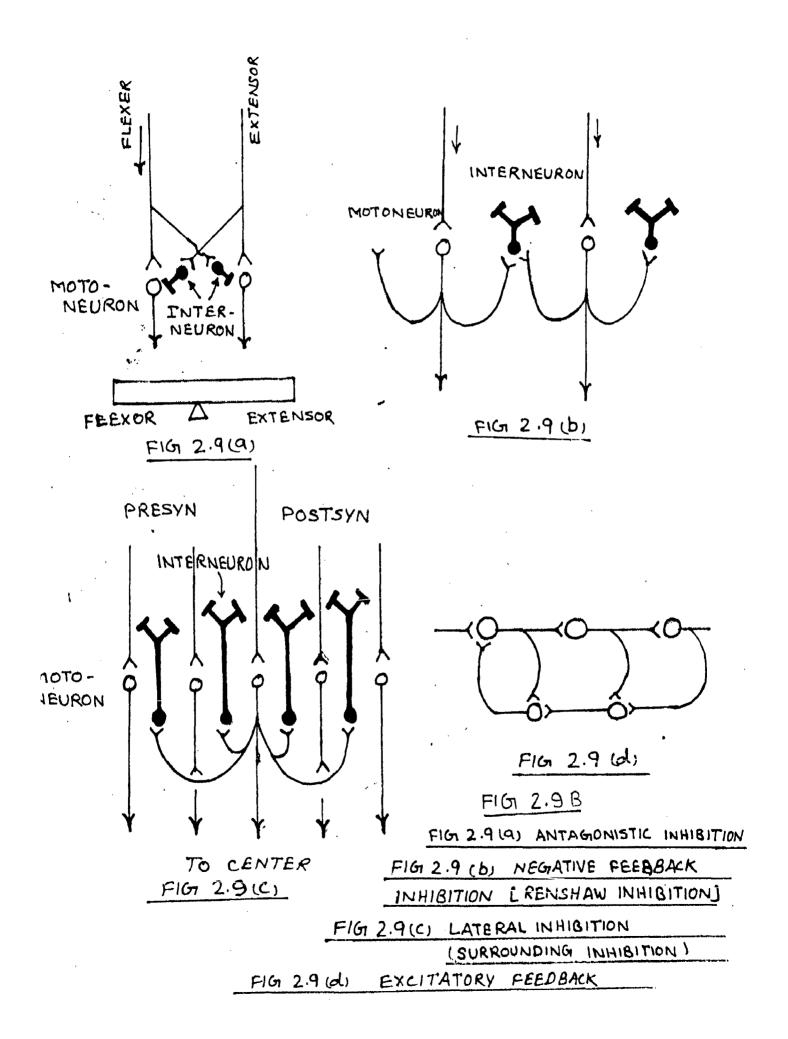
of action potentials at the nodes [2].

2.2.7 RESHAW CHLL:

Impulses arriving at central nervous system do not only produce excitation in a given neuron or nerve sentre but also in other neurons or nerve centres. This spread of excitation is known as irradiation. It is due to the numerous branching of the dendrites and axons and also due to shains of inter neurons connected to various nerve centres. This phenomenon of irradiation is obstructed by the inhibitory inputs at various nerve centres. An important role is played in limiting this irradiation by Remahaw Cell. It has inhibitory sympses with neurons. Remahaw Cell gives inhibitory inputs to neurons and its output frequency dependent upon level of excitation. Remahaw Cell acts as a protective device against excessive excitation. It forms a local negative feed back loop in the neuron and also with nearby meurons [3].

In Figure 2.4 (a) the antagonistic inhibition suppress excitatory events without influencing the excitatory process by which it was generated. Therefore, there is no feed back to the source of excitation [7]. On the other hand, the inhibitory interneuron in Figure 2.3 (b) act back as the cells by which they themselves were activated. In this case there is a negative feed back and this inhibition is termed as feed back inhibition. As Figure 2.3 (b) shows the motosxons give off collaterals to

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inhibitory interneurons whose axons in turn form inhibitory synapse on motoneurons [7]. This inhibitory inter neurons are called Renchaw Cells. As the moto neurons becomes more excited, the Renchaw Cells also become more excited, resulting in greater inhibition as the moto neurons after a short latent period (one inter neuron). This guarantees that weak moto neurons activity is transmitted undisturbed to the muscles while the excessive activity is damped to prevent hyperactivity of the muscles. The inhibitory inter neurons shown in dark in Figure 2.4.

A similar form of inhibitory feed back circuit frequently encountered in the CHS as shown in Figure 2.9 (0). The inhibitory inter neurons are connected in such a way that they act not only back on the excited cell itself (arrow) but also on neighbouring cells with the same function and in such a manner that these dells are particularly strongtly inhibited. This type of inhibition is called lateral inhibition because it ensures that an inhibited some is generated lateral to the excited some. Excitation is thus surrounding from all eides by an inhibited field, therefore, the phenomenon is also referred to as surrounding inhibition.

The CHS also contains positive feed back strouts which by feeding back excitation to already excited cells, would cause the excitation to move in a circle (reverberating excitation). An excitatory feed back circuit of this type is shown in

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Figure 2.3 (d). It could serve to maintain an induced activity for a long period. Hany people say [7] that short term memory is due to the reverberating of excitation in such positive feed back circuits, yst there is almost no experimental evidence to support this [7].

2.2.8 SOURCE OF THE ARRYE INPULSE:

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The impulse that travels along a nerve was once thought to be an electric current. In myelinated nerves of animals it travels at about the same speed as a bullet from a revaluer, the maximum velocity being about 90 to 120 mEtre/second. The speed of the nerve impulse is much slower in cold blooded animal. In the frog, at room temperature, the maximum velocity is about 30 mEtre/second. Conduction rates vary with the temperature, the kind of animal invalued, the diameter of fibre and the mature of the fibre covering, that is, whether or not the fibre is myelinated. In general, the largest fibres record the highest conduction rates and greatest spike potential and vice versa.

The nerve impulse is an action potential in the nerve fibre membrane that progresses along the nerve fibre, jumping from one node to another, and deriving its energy from metabolic sources within the neuron as seen earlier. This action is called the saltatory conduction. The action potential is self propagating and represents a progressive depolarization of the membrane. The nervous excitation is a merice of ionic changes

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resulting in a change of electrical sign, as the membrane excitation becomes much more permeable to sodium ions and at rest is is permeable to Potassium ions $\{K^{\Phi}\}_{+}$

The membrane resting potential is approximately -70mV (to the outside) and its action potential about 110 mV with respect to the resting potential [1]. In warm blooded animals, action potential duration is 1 to 3 mS [1].

2.2.9 SOURCE OF RESTING MEMBRANE POTENTIALS

The potential difference in rest state between the outer surface and its protoplasm is called resting membrane potential, which is of the order of -60 to -90 mV. Its origin has been explained theoretically as well as experimentally by Hodgkin and Huxley in 1952 [1]. According to their theory the bio-electric potentials are caused by unequal concentrations of K^+ , Bs^+ and Cl^- ions within the cell and outside it and by the variable permeability of the surface of the membrane to them. The protoplasm of merve and muscle cells contain 30 to 50 times as many R^+ ions, 6 to 10 times fever Bs^+ ions and 50 times fever Cl^- ions as does the extra cellular fluid [1]. Quick levelling of the difference of concentration is hampered by the extremely thin plasmatic membrane covering living cells (100°A).

The structure of this membrane is based on data obtained with the help of electron microscopy, X-Ray differaction and ohemical analysis. It consists of a double layer of phospholipid

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It is postulated that in the resting neuron, so called "Sodium pump" continually forces sodium ions outward through the membrane against an electro-chemical gradient. At the same time the potassium ions are able to move into the fibre. To maintain a ratio of 30:1, however, there must be same sort of active transport for potassium ions also. The energy for this active transport must come from the Cell's own metabolism. Chloride ions are able to diffuse through the cell membrane in either direction at equal rates. Actually chloride ions, being negative Cl tends to be repelled by the negative charge incide the fibre and are forced outward through the membrane. The initial negatively also tends to keep them outside. The interstitial fluid on the outside of the axon membrane is composed largely of sodium and chlorides ions, which represents about 90% of the ionic consentration, where ever such ions represent less than 10% of the total concentration inside the fibre. Hembrane potential can be get from Hernst's equation [33]

- $V = \pm \frac{RT}{T} \lambda_{\rm B} \frac{C_{\rm B}}{C_{\rm A}}$
- R . Gas constant
- T . Absolute temperature
- F . Parader constant
- C. External concentration
- C. . Internal concentration

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molecules lines on the inside and on the outside with a layer of molecules of compound earbohydrates mucopoly-saccharides. In the cell membrane there are minute channels or pores a few "A in diameter, through which molecules of water, ions and other substances pass in and out of the cell as shown in Figure 2.10.

It is supposed that the presence of dissociated phosphate and carboxyle groups is the reason why the membrane of merve fibre is much less permeable to amion than that the outions. Permeability of different cations also varies and changes regularly in the different functional conditions of the tissue. At rest, the permeability of merve fibre membrane to X^+ ions is between 20 to 100 times that to Na^+ ions, whereas in the excited state, the ratio is reversed.

In a state of physiological rest the diffusion of positively charged K^+ ions from protoplasm to external fluid gives a positive charge to the outer surface of the membrane and a negative charge to the inner one. Experiments have shown that the concentration gradient of K^+ ions is really the principal factor determining the value of the resting potential of the neuron [1].

In the resting neuron, the sodium ions, which are positive, are in excess outside the membrane in the ratio of about 10:1. Potassium ions, also positive, are in excess within the fibre, the ratio being 30:1. It is obvious that these ratios represent a high degree of ionic unbalance.

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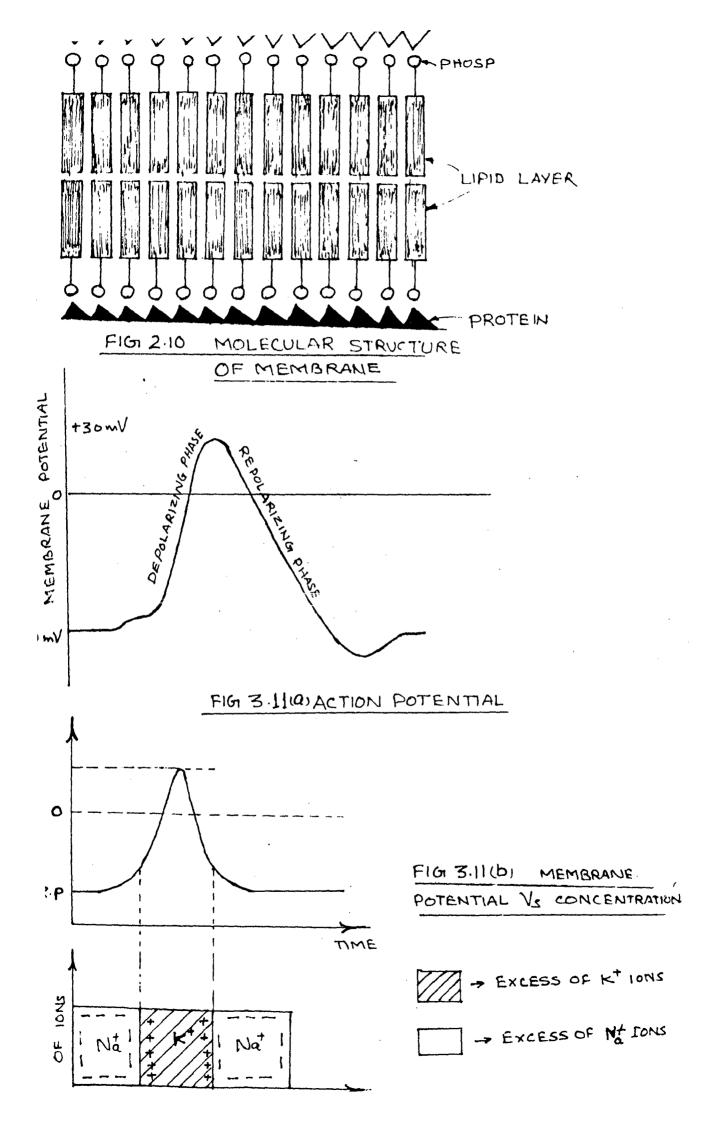
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2.2.10 SOURCE OF ACTION FOTENTIALS

The reason for the appearance of an action potential in the nerve and a muscle fibre is a change in the ion permeability of the membrane. The membrane permeability to potensium in a state of rest, exceeds that of the sodium. As a consequence, the flow of positively charged Potensium ions from the protoplasm to the surrounding fluid exceeds the contrary flow of Sodium Gations from the outside into the cell, so that at rest the outer side of the cell body membrane is electrically positive to the inner one [2].

Under the effect of a stimulus on the cell, membrane permembility of sodium ions increases remarkably to a point where it is approximately 10 times that of potassium ions. The flow of Ma⁴⁴ ions from the surrounding fluid into the protoplasm therefore begins to exceed the outflow of potassium ions considerably, which reverses the sign of the membrane charge, its outer surface becomes electrically negative to its inner surface. The change is registered as a rise of the action potential curve (depolarization phase) Figure 2.114 & 2.115.

The increase in permeability to sodium ions continue in nerve fibres for only a very short time, and is followed by the appearance of restorative process in the cell that lead to new decrease in membrane permeability to sodium ions and an increases in that to potassium ions.



The process leading to a fall in the modium permeability of the membrane is called inactivation by Hodgkin. As a result of inactivation the flow of positive Ha⁺ ions into the protoplasm in charply reduced, while a simultaneously increase in potassium permeability intensifies the flow of positive H⁺ ions out of the protoplasm into the currounding medium. The two processes results in repolarization of two membrane, its outer purface again acquires a positive charge and the inner surface a negative one. The change is registered as a descending part of the action potential curve (repolarization phase) as shown in Figure 2.11.

The clocurical model of the nerve cell is as shown in Figure 2.12.

The ourrent flour

 $\mathbf{1} = \mathbf{0} \frac{\mathrm{d} \nabla}{\mathrm{d} \mathbf{r}} \diamond \sigma_{\Pi \alpha} (\nabla - \nabla_{\Pi \alpha}) \diamond \sigma_{\mathrm{lc}} (\nabla - \nabla_{\mathrm{lc}})$

Curront flows through Gi, 15 Very small as compared to others, shore

> $G_{IIQ} = Sodium pornoability conductance$ $G_{K} = Potaccium pernoability conductance$ $G_{L} = Chloride permoability conductance$ At steady otates $<math display="block">\frac{At + bady - bates}{dy - b}$ $V = \frac{G_{IIQ} - V_{IIQ} + G_{K} - V_{K}}{G_{IIQ} + G_{K}}$

Here V V V

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At resting states

 c_k is larger than $c_{N,n}$ and so V is nearer to V_k than to $V_{N,n}$.

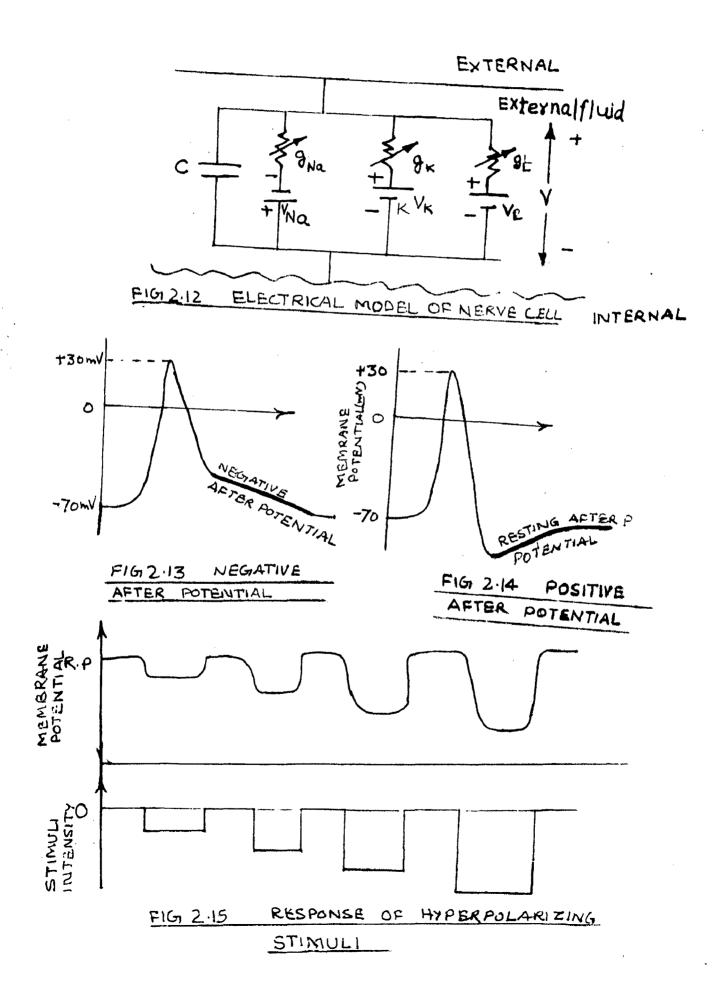
MEGATIVE AFTER POTENTIAL:

The repolarization phase of the action potential is divided into two parts of unsqual duration. At first depolarization of the membrane proceeds quickly, then there is a slackness and finally stops, and it is at this moment the beginning of the negative after potential starts. The membrane remains partly depolarized for a certain time and complete restoration to the initial potential of -85 aV occurs after approximately 15 millisecond [1] Figure 2.13. Negative after potential is often called after depolarization of the membrane. This is apparently due to membrane permeability to sodium ions remaining increased for a specificitime after termination of the action potential as compared with initial level.

POSITIVE AFTER POTENTIAL:

Positive after potential occurs before the depolarising phase start and it is well seen in unsyelinated newse fibre Figure 2.14 [4]. The positive action potential is due to the fact that membrane permeability to K^+ ions remains heightened for a time of termination of the action potential as compared with the imitial level. An increase in the flow of potessium ions

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from the protoplasm leads to an increase in membrane potential i.e. to an after hyper polarisation of the membrane.

2.2.11 THE ACTION POPERTIAL AND FREQUENCY CODING:

Any voltage applied to the electrode, which is inserted into the aron acts as stimulus. If a brief stimulus is applied to the agon (a stimulus resulting in a perhaps 15 mV depolarization) the response of aron is an action potential. This action potential consists of a brief (approximately 0.5 willi second) fluctuation in membrane potential with a characteristic configurations the membrane potential undergees a large, rapid depolarisation followed by a slightly less rapid return to the resting potential (Fig. 2.11). The yeak depolarization makes anon positive on the inside briefly. that is, the depolarization is so large at the yeak of the action potential that the sign of inside-outside potential differences actually reverse from negative to positive (+30 mV). It is called ascending phase. During the descending phase the membrane polarization reverts to the resting level is known as repolarization phase. The length of the action potential in nerve and skeltal muscle fibres varies from 0.1 to 5 mS during which repolarization phase is always larger than the depolarisation. Cooling of the fibres by 10°C makes the action potential approximately three times larger [2], specially its descending phase.

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When hyperpolarising stimulus (megative) is applied through the electrode, no action potential results, but rather the membrane petential simply follows the stimulus with slight distortion, as in the case of dendrities, shown in Figure 2.15.

Because the amon's response to the hyperpolarisation is simply a reflection of the stimulus, it can be said that hypderpolarising stimuli result in a passive response, while depolarizing stimuli result in an active response i.e. action potential.

For a very small depolarizing stimuli, only a passive response results the response simply mirrors the stimulus with slight distortion. This passive response is identical to the one seen with hyper-polarizing stimuli, except, of course, that the direction is reversed to mirror the depolarizing stimuli applied as shown in Figure 2.16.

is the intensity of the stimulus is gradually increased, the magnitude of the passive response increases proportionally. With still further increase in stimulus strength a new active component of the stimulus is removed, a small jump is seen on the falling phase of the passive response (Figure 2.17).

As the stimulus magnitude is made still large, this bump grows in size. Finally, when the stimulus intensity is increased beyond threshold value, an action potential generated. Further increase in the stimulus intensity produce no further increases in the size of axon's response, all action potentials are of same size irrespective of the stimulus magnitude as shown in Figure 2.18.

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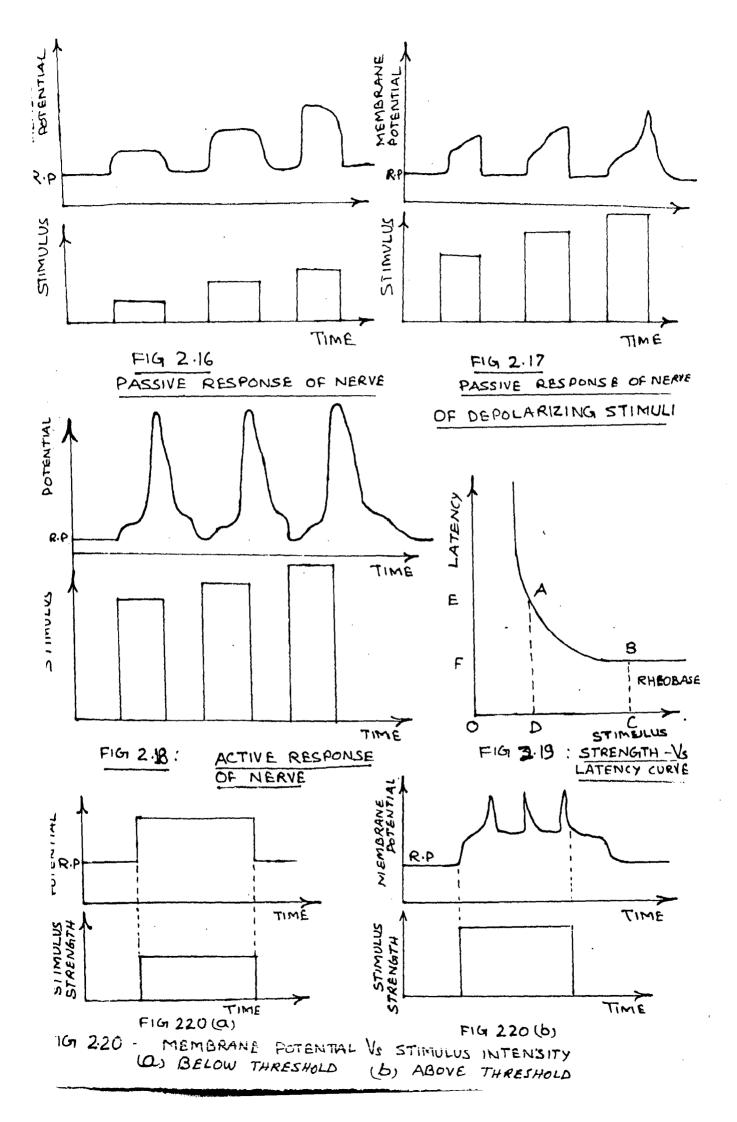
Thus, whenever stimulus beyond threshold value is available, action potential is generated whereas no response results if stimulus is less than threshold. This property of axon is known as "all or none lay".

The interval between the onset of the stimulus and the peak of the action potential is known as latency. It decreases systematically as stimulus magnitude increased. Thus stronger the stimulus, the shorter the latency. A graph of latency as a function of stimulus strength (Figure 2.19) is known as a strength latency curve, it has approximately the same shape for different types of axons although the range of latencies observed may be very different.

The phenomenon of frequency coding is a consequence of several properties of the action potential. Frequency coding means, the coding of the information in terms of the impulse frequency [2].

If a long duration sub-threshold stimulus is used, it will simply produce depolarization lasting for the period of time that the stimulus was applied. However, if a long lasting above threshold stimulus is based, action potential will generate. Immediately after the first action potential the situation is complicated by the presence of a stimulus during the absolute refractory period when another action potential is not possible. In one type of exem the threshold returns from its high value to the resting level and eventually reaches a point at which the

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maintained stimulus is effective in causing a second action potential. The same process will remoccur again and again as long as the stimulus is maintained, repeatedly, giving rise to action potential as shown in Figure 2.20.

By similar reasoning it is possible to deduce the relationship between nerve impulse frequency and stimulus intensity for the type of neuron which is considered.

The repetative occurence of nerve ispulses in response to maintained depolarization was predicted on the basis of the refractory period; after one action potential has occured, a certain amount of time is necessary for the threshold to return to a level where the maintained stimulus is again able to evoke a second action potential. If the stronger stimulus was used, however, there would be a shorter interval between successive impulses since the threshold would not have to return to as low level for the larger stimulus to be effective. Thus nerve impulse frequency would increase as the magnitude of a maintained depolarization increased.

The strength - latency relationship provides a second reason why increasing stimulus-strength produces a higher nerve impulse frequency.

The all or mone law, which states that the size of an action potential is independent of the magnitude of the stimulus which produces its means that information about stimulus intensity

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must be carried same way other than response magnitude. An alternate means of coding information is provided by the properties of refractory period and strength-latency relationship; information about stimulus intensity is contained in the number of merve impulses occuring per second. The relationship is shown in Figure 2.21.

Same axons do not produce action potentials repeatively when it is subjected to a constant depolarization, but rather produces only one or several action potential at the onset of the stimulus and then becomes silent inspite of the continuing depolarization. This phenomenon is usually called <u>accommodation</u>. Usually only the initial segments near the cell body translate depolarization into nerve impulse frequency.

Excitation of some neurons depends not only on stimuli strength and duration but also on the steepness of its increase. When the steepness of the rise is reduced below a certain minimum value, no action potential appears, no matter how great the final strength of the current. This is because of the fact that during the period of increase in stimulus strength, active changes occur in the tissues raising the threshold and interfering with stimulation. This phenomenon is known as <u>adaptation</u>. The phenomenon of adaptation of excitable tissue to a slowly increasing stimulus is known as <u>accommodation</u>.

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EICITATORY POST-SYNAPPIC POTENTIAL (PPSP):

Since the synaptic cleft is very marrow (about 200A) the mediator quickly (0.5 milli second) diffuse to the post-synaptic membrane and interact with its structural components when impulse is applied. This results in considerably increase in permeability of the post-synaptic membrane to sodium and potassium ions which is followed by its depolarization and the FPSP appears [4].

INBIBITORY POST-STNAPTIC POTERTIAL (IPSP):

The impulse generated by inhibitory neurons, which are present in the spinal cord and in brains, is arrived at the nerve ending along the axons cause secretion of a mediator which does not depolarise the post-synaptic membrane, but on the contrast, hyper-polarises it. The hyperpolarisation is registered in the form of an electrical positive wave described as IPSP.

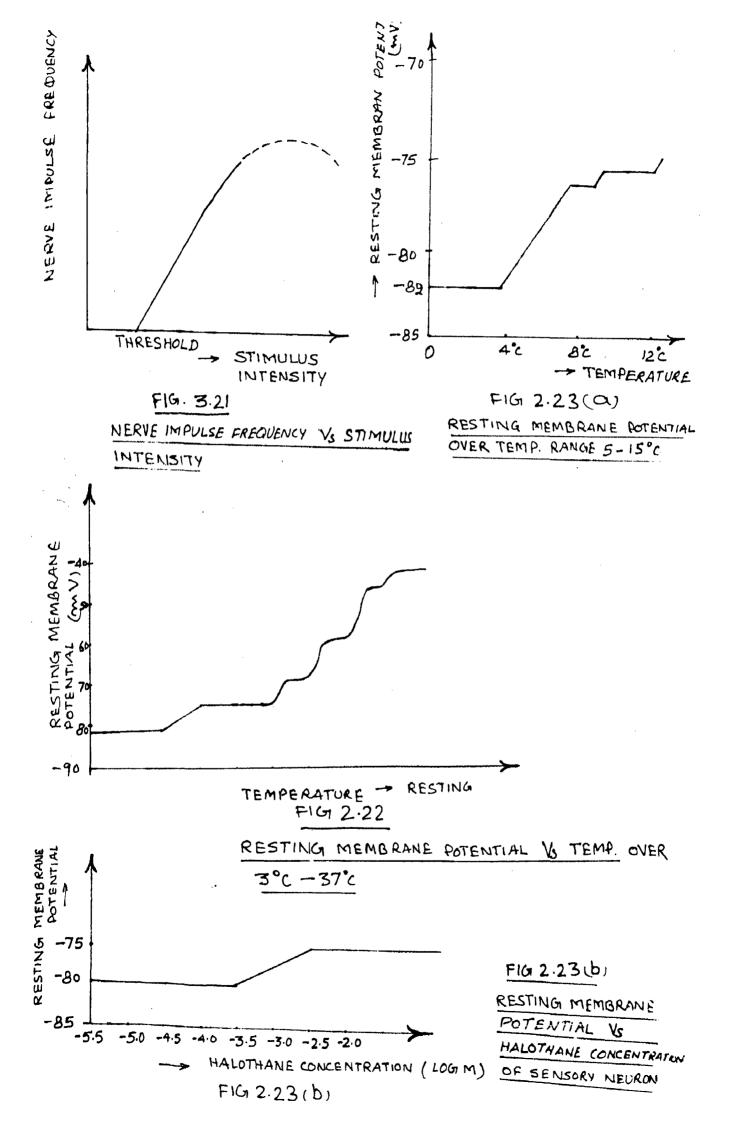
2.2.12 THE EFFECTS OF TEMPERATURE ON NEURONAL EXCLUSION INT.

The effect of temperature ever the range of 30°C to 37°C, on the membrane was studied by Hao Ever [22].

The experiment was conducted to carry out the effect of temperature. It was shown that the inter-cellular electrode diffusion potential and tip resistance varied considerably with temperature. The following results were made.

I. DEPOLARISATION:

Resting membrane potential depolarised from -82.5 2 0.5mV



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at 3°C to -47 ± 0.5 at 37°C. The rate of change was not linear figure 2.22. The change in potential as the function of temperature occured in a step like manner, which may reflect transition changes of the membrane at oritical temperature.

II. <u>REMBRANE RESISTANCE</u>:

The membrane resistance was reduced from 4.1 Hohms at 3°C to 1.2 Hohms at 37°C. The relationship between membrane resistance and temperature is non-linear, and occured in a step like manner similar to the effects observed with resting potential. The brank point for both relationship 2.23 (a) & (b) occured at similar temperature.

Halothene produce depolarisation Figure 2.23 (b).

III. ACTION POTENTIAL

The amplitude of action potential decreased by 60 to 90 mV as temperature was increased (Figure 2). At 3°C the antidromic spike amplitude was 110 mV (average) and at 37°C the amplitude had decreased to 20mV. The spike duration decreased and conduction velocity increased as temperature was raised.

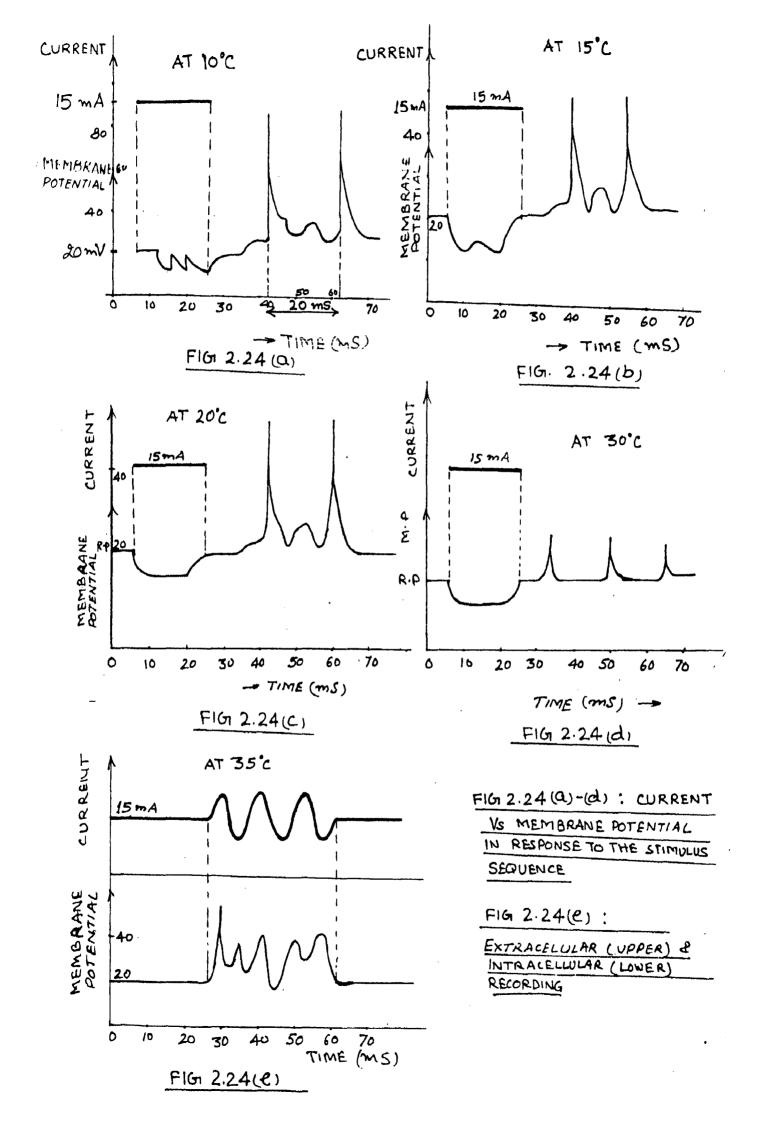
The amount of depolarization current required to produce a spike via the intra-cellular electrode depressed as temperature was raised i.e. the threshold for spike initiation decreased Figure 2.24.

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At temperature beyond 28°C, spontaneous discharge activity was observed (Figure 2.24 (d). This may reflect the high level of depolarisation produced at these temperature. The normal discharge pattern of mingle action potential was also altered at temperature of 28°C or greater, such that multiple spikes or bursts were produced in response to a single stimulus imput (Figure 2.23 (e). <u>SYNAPTIC TRAESNISSION</u>: The IPSP duration decreased as temperature was increased. Complete depression occured at approximately 20°C.

All the effects observed were reversible over the temperature range from 3*C to 37*C. The temperature above or below this range usually produced cell death. In few cells hystresis was observed when the temperature was raised and subsequently lowered back to previous level.

The observed decreases of membrane resistance, spike threshold and action potential, amplitude were consistent with the depolarization of the resting membrane potential produced by higher temperatures.



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CHAPTER - 3

REVIEW OF REURAL MODELLING

3.D INTRODUCTION:

The history of the neural modelling is one of many false starts, dead ends, and continual grouping. Progress has seldom been rapid and has often been frustrating. The advances, nonetheless, is measurable. The advances has, in fact, been substantial.

Neural analogs take a variety of forms, ranging from informal, verbal models to highly elaborate physical and mathematical constructs. Most models that have appeard[5] during the last half century or so have taken the form of chemical systems, electronic circuits, mathematical formulation, or computer simulations.

Considerable advantages and serious short-comings are found in each, although for a given modelling problem there is generally little difficult in selecting the most appropriate technique. Since mathematical, electrical, electronic and computer simulation models comprise the majority of contemporary analogs, it is of interest to examine some of their intrinsic merits and deficiencies.

Mathematical models have great utility in limited domains. They are invaluable in cases where the number of variables is reasonably limited and non-linearities do not present

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severe analytical difficulties. An outstanding application of this type of model is found in the analysis of membrane biophysics. Formal mathematical description, however, is simply unable in its present state of development to deal adequately with the multivariable non-linear non-linear complexities of entire neurons, complete net-work analysis is even more formidable.

In certain special cases, however, mathematical models of net-work behaving are extremely well qualified. This is particularly true for statical treatment of large ensembles and for the analysis of large scale electrical activity such as wave formation and propagation.

Hestronic models can simulate continuously variable and non-linear operations accurately and economically. Providing real time signals that may be observed while experimental conditions are manipulated, they permit a rapid and effective kind of observer model interaction not easily achieved by other techniques. There is considerable advantage of direct observation of wave forms, phase relationship, modulations, and time dependent inter-actions while stimuli and model parameters are changed. Such advantage is most effective for the modelling of one or few inter-connected units. For large net-works, however, both observation and manipulation of parameters and connections becomes very difficult.

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Analog computers have advantages similar to those of electronics models, but tend to be alow and cumbersome. Both have the advantages over mathematical models that they do not tend to compel over simplification.

The growing speed and storage capabilities of digital computers carry great promise for flexible, realistic modelling.

In this review the author has discussed electrical and electronic model of the neuron. This review is representative rather than exhaustive. The author attempts to delineats the mein stream of activity in neural modelling and to emphasize what seem to be important directions and achievements.

In this review the author restrict to models of fixed properties of membrane, single unit and relatively small met-works only. There has been no attempt was made to include mathematical models, chemical models and models of information storage i.e. analogs of memory, conditioning or learning. Emphasis throughout is on the dynamic information-processing aspects of nervous systems.

The following electrical and electronic sodels are critically examined:-

- 1. Rodskin-Hurley's Model of Heuron
- 2. Levis model of Neuron

5. 0. Roy's Hodel of Squaid Axon membrane

- 4. R.C. Nodel of nerve fibre
- 5. RLC model of nerve fibre

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6. Lowis model using Ballastic Net-works

T. Hodel based on double emergy element system

8. Ionic transistor model of neuron

9. Heural model based on low-pass & high-pass net-works

10. Barman's model of neuron

11. French & Stein's model of neuron

12. Dendritic compartment model of neuron.

13. Hodel of neuron by Naguno

14. Electronic model of Heuron with feed back through Renshaw Cell

15. Biophysical model to explain Herve Impulses

3.1 HODGKIN-HUXLET'S HODEL:

In this model electro_chemical effect is taken into account for the modelling of neural mystem. Hodgkin and Huxley proposed a mathematical model [5, 12] for squid nerve to meet the experimental results.

The general equation for the action potential for model shown in Figure 5.1.

$$\frac{1}{Rax} \xrightarrow{B_{n}(y, t)} = C_{n} \xrightarrow{R_{n}(y, t)} = S_{Ra}(E_{n}(y, t) - E_{n})$$

$$+ C_{n}(E_{n}(y, t) - E_{n})$$

where g_{Ha} and g_{K} represent the unknown conductance functions; conductance will be functions (at least) of membrane potential and time.

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$$\mathcal{L}_{\text{Ha}} = \mathcal{L}_{\text{Ha}}$$
 (E_k, t) and $\mathcal{L}_{\text{K}} = \mathcal{L}_{\text{K}}$ (H_k, t)

The above equation is very complicated.

The membrane current is exactly whatever current is applied from external sources.

 $I_{membrane} = I_{mp} = I_m = C_m \frac{\partial E_m}{\partial t} + E_{ma} (E_m - E_m) + E_k (E_m - E_k) + E_l (E_m - E_k)$

Here SNA a conductance of sodium dependent on the membrane voltage & time

- Sk a condutance of Potassium dependent on the membrane voltage and time
- Acakage conductance which is independent of
 voltage and time

These three ionic components are in parallel.

C_ - membrane dapacitance,

Br, E and A are the constant voltage

E - nembrane voltage

V = Displacement of membrane potential from its resting Value

 $s_{\text{He}} \left(\mathbf{x}_{n} - \mathbf{x}_{n} \right) + s_{\text{L}} \left(\mathbf{x}_{n} - \mathbf{x}_{n} \right) + s_{\text{L}} \left(\mathbf{x}_{n} - \mathbf{x}_{n} \right)$

- Institution where IL - leakage current

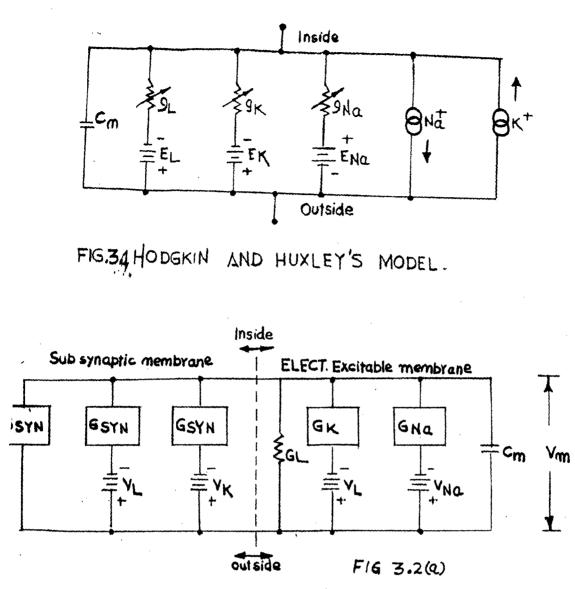
R is the potential at which leakage current due to chloride and ions is zero. The Ha conductance increased when the aron was depolarized, and then decreased again in the presence of steady depolarization is called acdium inactivation. The decrease

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in modium conductance with maintained depolarization is termed modium inactivation, and the conductance increases are called potassium and modium activation. Hodgkin and Huxley found emperical equations describing these functions. The pair of equation describing the potassium conductance are ----

> s. - 5, 24 $\frac{dn}{dt} = dt_n (1-n) - \beta_n \cdot n$ where $\alpha_n = \frac{0.01 (V + 10)}{(V+10)/10}$ B = 0.125 + 1/80 E. = Maximum potassium conductance (a constant) are functions of voltage but not of time n . Dimensional variable having a value between 0 and 1. Sus = Ten mb $\frac{dn}{dn} = \alpha_n (1 - n) - \beta_n \cdot n$ $\frac{dh}{dt} = a_h (t-h) - \beta_h \cdot h$ $\alpha_{\rm m} = \frac{0.1 (V + 25)}{(V + 25)/10}$ B= _ V/18 × = 0.07 - V/20 B = - (++30)/10

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2(a) GPARALLEL ELECTRONICS CKT. SIMULATED BOTH BY SYNAPTIC & ELEGTRICALLY EXCITABLE MEMBRANE

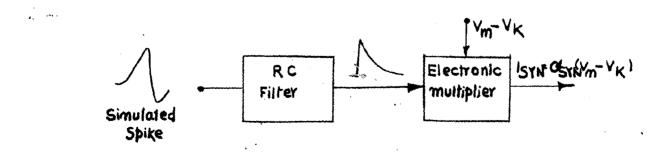


FIG.32(b) NEURONAL MEMBRANE MODEL BY LEWIS

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From this we gathered -

1. Permembility appears to depends on membrane potential and not on membrane current.

2. If Ha concentration is much that E_{A} E. Ha current is onward. If E_{A} E, the current changes in sign but follows same time course.

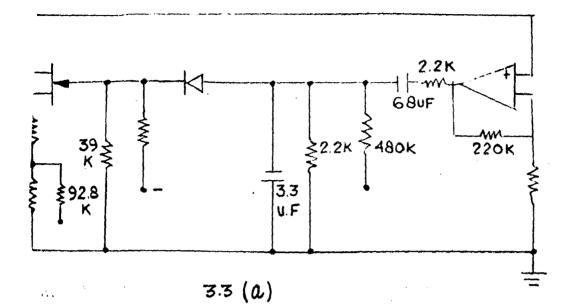
3. At fixed depolarisation of sodium current follows a time course whose form is independent of current through membrane.

3.2 LERIS HODELS:

The model [1] consists of seven parallel circuits and includes the synaptic membrane analogs. Fine conductance out of six are constant and they undergoe transient change owing to either to change in synaptic imputs or to change in trans-membrane potential (V_m) . The current through each conductance is the product of time varying conductance itself and the time varying voltage across it. Figure 3.2 illustrates the operation of simulated synaptic conductance. In case of synaptic conductance, Figure 3.2 (b) a pro-synaptic strike is transferred into a decaying exponential by means of a RC filter. The exponential represents the time course of synaptic conductance. The multiplier circuit produces a current proportional to product of condutance and voltage (Vm - Vk) across it.

5.5 G. RAY'S MODEL OF SQUID ANON MENBRANES

The electronic model proposed by G. Ray is based on the H-H medel. According to H-H theory, sodium and potassium



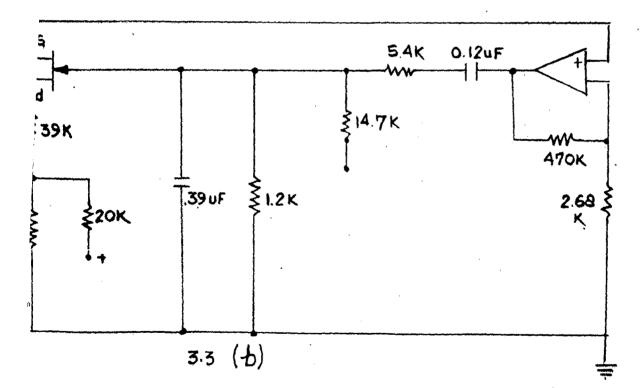


FIG 33 G.ROY MODEL

(a) SIMULATION OF POTASSIUM CONDUCTANCE

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(+) SIMULATION OF SODIUM CONDUCTANCE

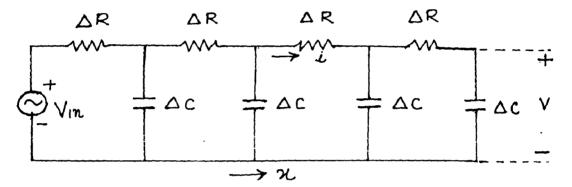
condutances have very low values in their resting state. When an external voltage is applied across membrane, the conductances of both are increased, when the applied potential is large, they reach a saturation value beyond which they remain constant. G. Ray [17] found that FET is the ideal electronic element to simulate the axon membrane condutances.

One PET is used for $g_{\rm R}$ and one for $g_{\rm RR}$. The voltage across axon membrane is represented by drain-source voltage (Vds) and current by the drain-source current Ids. Hegative bias is on the gate of PET for resting state. As the Vds is feed back via an intervening circuit to the gate for providing voltage with dependence of condutance $g_{\rm ds}$. The $g_{\rm ds}$ becomes time-dependent with the introduction of RC in the feed back circuit. An ampis used to amplify the Vds and to isolate the PET from the circuit determining the time dependence of $g_{\rm ds}$. The -Ve biases are adjusted so that the diode is non conducting when Vds = 0. The coupling capacitor is much smaller in order to provide faster imactivation for the Ka⁺ conductance.

3.4 <u>RCM NODEL OF KERVE FIBRE</u>

The equivalent RC analog of axon [3, 12] is shown in Figure-34. These models are like the transmission line of power system. The remistance and capacitance are distributed along the length. The number of Remistances (R) and Capacitances (C) parameters depends upon the length. The voltage & current can be calculated from the differential equation at any point of model.

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FIG 3.4 R.C. MODEL OF NERVE FIBRE

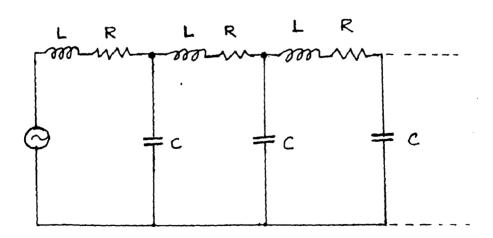


FIG. 3.5. RLC MODEL OF NERVE FIBRE

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3.5 RLC MODEL OF REATE PIRCE

It is equivalent to the long transmission line [3, 12]. The R, L and C parameters are distributed all along the length of the fibre length. The value of current and voltage can be get by solving the differential equation of the net-work. The fibre section is assumed to uniform throughout.

The RLC model (Figure 3.5) is assumed superior than HC model due to following reasons:-

1. The actual phenomenon is considered

2. The realistic wave form may be considered

5.6 LINIS MODEL USING BALLASTIC ENT-WORES:

The Lewis model [1, 12] is based on the fact that the neuron is functionally much more complex than as thought of in the classical view where the synaptic region was considered to be soupled directly to a spike. A simple RC realisation of a ballistic net-work is shown in Figure 5.6 (a). In simulating the ballistic responses Lewis assumes three parameters.

1. Rise time which is determined by Ro Co

2. Fall time is determined by (C; // C2).R2

3. Maximum amplitude

The impulses originating in pre-synaptic neuron, transmitted through inter-cellularly, induce a charge in the synaptic

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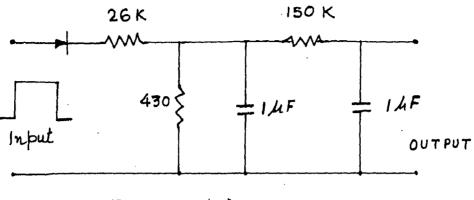
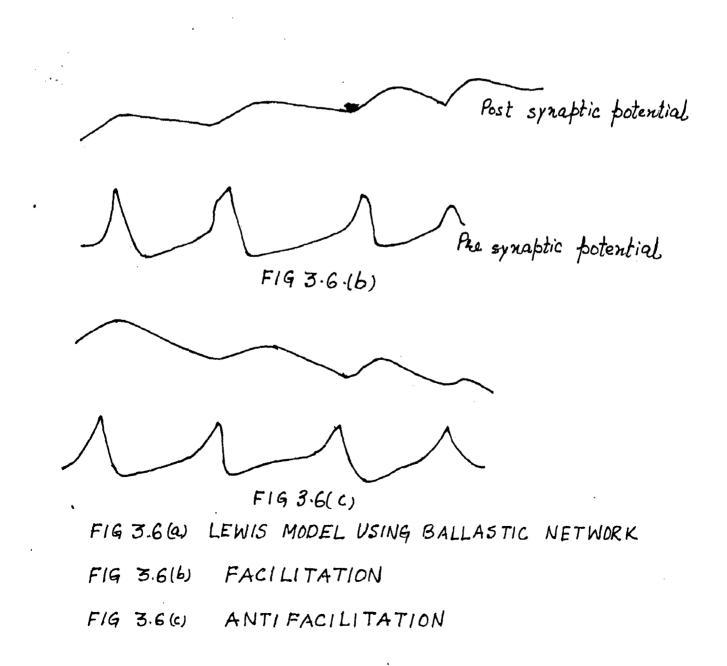


FIG 3.6 (a)



membrane of post-synaptic neuron. Thus, a single pro-synaptic spike induces a slowly varying, long lasting post-synaptic potential known as ballistic potential. And the formation is not completely understood.

There are two important mechanisms ----

<u>FACILITATION</u>:- The first impulse conditions the synapse in such a way as to enhance or facilitate subsequent responses, Figure 3.6 (b).

ANTI-FACILITATION:- The first spike reduce or antifacilitates the response. Pigure 3.6 (c).

An inhibited neuron, when inhibiting stimulus was deased, was found to fire spontaneously. This implied that there was a rebound or negative after effect. In a similar manner an excited neuron, on dessation of prolonged excitation may go through a period of depressed excitability.

3.7 NODEL BASED ON DOUBLY ENERGY VLENERT SISTEME

The system responses depends upon the physical characteristics of the energy storage element, Figure 3.7 (a). Circuits containing the energy storage elements have pales approximately widely enough so that the transfent response can be approximated by treating them as two isolated single energy circuits. [16]

Let a step voltage V_i is applied. For full charging surrent which flows after the excitation is applied, is determined by the input capacity C_{i} . The same change is accumulated in C_{i} .

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Since $C_{Q} = C_{Q}$, the voltage changed across Q_{Q} will be very small, which C_{Q} charged fully. Thus C_{Q} can be assumed short circuited during the entire interval. The equivalent circuit is now reduced to a circuit containing a single energy storage Figure 3.7 (b).

Now we can get the following relationships from the circuita:--

$$v_{01} = v_{851} (1 - \bar{*}^{*/} 1)$$

$$t = C_{0} (B_{0} // B_{1} // B_{0})$$

Q discharge through

$$2 = C_0 (R_0 + R_1 // R_0)$$

The final response equation.

$$v_0$$
 (t) = $v_{351} = t^{1/2}$

Since decay time is very large, error introducing by starting the decay anywhere in the vicuity of 2580 will be negligible.

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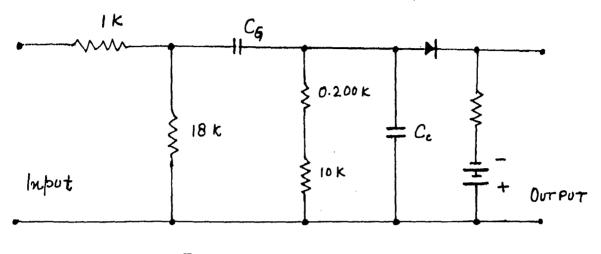


FIG 3.7 (2)

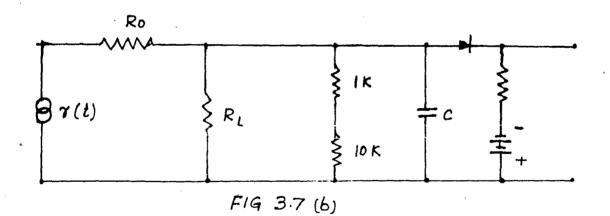


FIG 3.7(6) MODEL BASED ON DOUBLE ENERGY ELEMENT FIG 3.7(6) EQUIVALENT CIRCUIT OF E.M. SYSTEM

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5.8 IONIC TRANSISTOR MODEL:

An equivalent circuit of transistor model is given in Figure 3.8 (a).

A voltage step is applied. The behaviour of ionic currents are studied by the method of Laplace transform techniques. Concept of membrane conductivity modulation is used to calculate the various parameters of ionic transistor.

Vhere

r. - Membrane resistance

C. . Membrane capacitance

- s = Junction resistance between membrane and external solution
- r = Junction remistance between internal solution and membrane

Since the external solution is usually at or referred to as the ground potential, a nerve has so called grounded emitter configuration. A stimulating potential is applied between external

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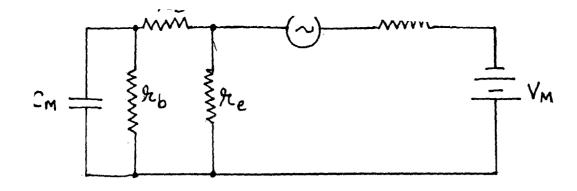


FIG 3.8 (a)

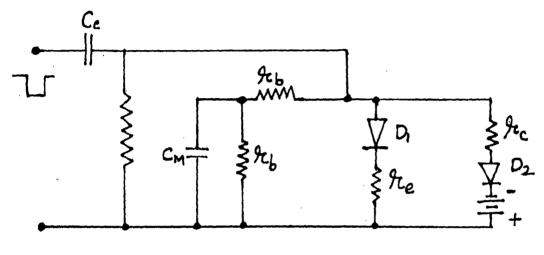


FIG 3.8 (b)

FIG.3.8(2) EQUIVALENT CIRCUIT OF IONIC TRANSISTOR MODEL FIG 3.8(6) EQUIVALENT ELECTRONIC MODEL OF NEURON

solution and axoplasm. Part of the potential will appear across the outer junction, and the rest across membrane. Due to this applied voltage, ourrent start flowing.

When applied step voltage is greater then the voltage providing at reserve bias across the diode D_1 show in Figure 3.8(a) the membrane capacitance C_R discharges through the diode D_1 with time constant equivalent to

$$\left(\frac{x_b (x_b + x_e)}{x_b + x_b}\right) CR$$

Once capacitance $C_{\rm H}$ is discharged it starts getting charged up with time constant of $(R_0 + R_0)$ $C_{\rm H}$. During the discharge period of $C_{\rm H}$ sodium currents flows, and during the oharging phase of $C_{\rm H}$, sodium current decreases while K^+ current increase to saturation value. Using an equivalent dircuit of ionic transistor, and applying Laplace transform technique, the expressions for sodium and potassium currents are obtained.

Applying a Laplace transform for the step voltage excitation, and writing loop equation for mesh one and two in Figure 3.8(b) The expression for sodium and potannium currents can be obtained. It is seen seen step voltage excitation is applied between intra-cellular and extra-cellular solution. Nost of this applied step voltage occurs across membrane region, as the resistivity of these solutions are negligible compared to the membrane. The expression for time constant

$$T_{\text{He}} = \frac{r_{b} (r_{b} + r_{c}) C}{(2 r_{b} + r_{c}) (1 - \frac{2r_{b} r_{c} - r_{c}}{2 r_{b} (r_{c} + r_{c}) + r_{c} r_{c}})}$$

ind similarly $T = T_k$ for the rise of potassium currents by adjusting different parameters as R_0 , R_0 and R_0 . The different shapes of the wave form can be obtained required for the action potential. It is also satisfying the steady state conditions.

3.9 NEURAL MODEL BASED ON LOW PASS & HICH PASS MER-WORK:

In this model [12], there is one low pass and one high pass not-work, connected in cadcade as shown in Figure 3.9 (a). The successive net-works do not load each other. The response can be separated into two regions, both the regions depends upon the individual characteristics of energy storage element.

· V₁ = Input voltage

 $V_2 = O/P$ of low pass = I/O of High Pass $V_3 = O/P$ of High Pass

So, V_R = Hembrane Rosting Potential

 $V_2(t) = V_1(1 - \tilde{e}^{t/\tau_1})$ where $\tau_1 = B_1 C_1$ $V_3(t) = V_2^{-\tilde{e}^{t/\tau_2}}$ where $\tau_2 = B_2 C_2$

The block diagram shown in Figure 3.9 (b) consists of threshold unit and pulse generating unit and wave shaping direct. The differentiated input is applied to threshold direct. If imput is greater than threshold level, the multi-vibrator triggers. This pulse output is fed to the wave shaping direct which converts the pulse into spikes to satisfy the steady state and transient conditions.

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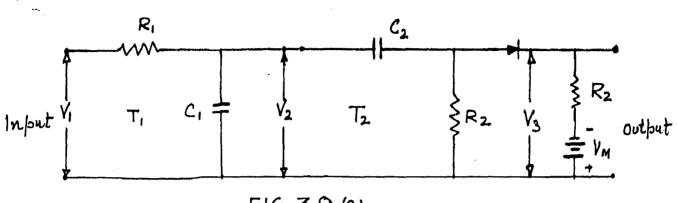


FIG 3.9(4)

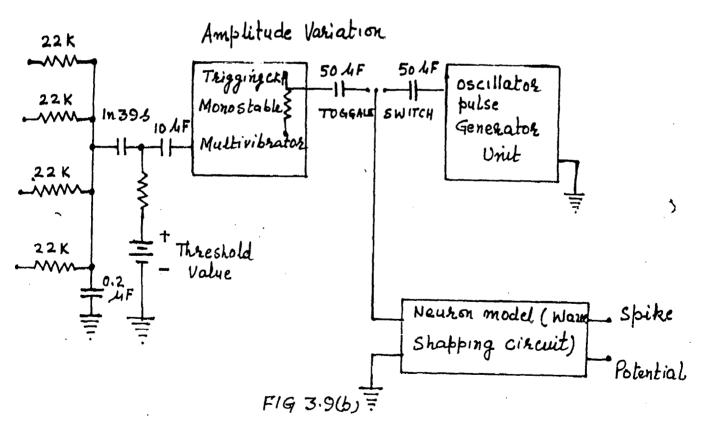


FIG 3.9(9) MODEL BASED ON LOW PASS AND HIGH PASS NETWORK FIG 3.9(b) BLOCK DIAGRAM. OF NEURON

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5-10 HARNON'S MODEL

Harmon [1] proposed an electromic model of Heuron by using the transistors, as shown in Figure 3.10, to show the imput output properties of neuron. In this model following four basic properties of neuron are provided:-

- a) Spatial and temporal summation
- b) All or nome law
- o) Absolute refractory period, and
- d) Graded inhibitations

The time constant of monostable multi-vibrator shows the absolute refractory period.

3.11 ERENCE AND STOTK'S ANALOG MODEL:

The block diagram of the model [18] is shown in Figure The model consists a leaky integrator, threshold level Comparator and pulse generator. Leaky integrator sums the various imput over a period determined by the constant γ_i of the integrator. As the integrated voltage exceeds the threshold level, the comparator send a signal to the pulse generator which gives pulses at the output. The pulse duration determines the absolute refractory period which we can adjust by charging the passive parameters of the pulse generator.

Subthreshold voltages are fed to increase the threshold level with a second time constant \succ_2 , so that the avalog show accommodation to slowly rising inputs. Much output pulse resets

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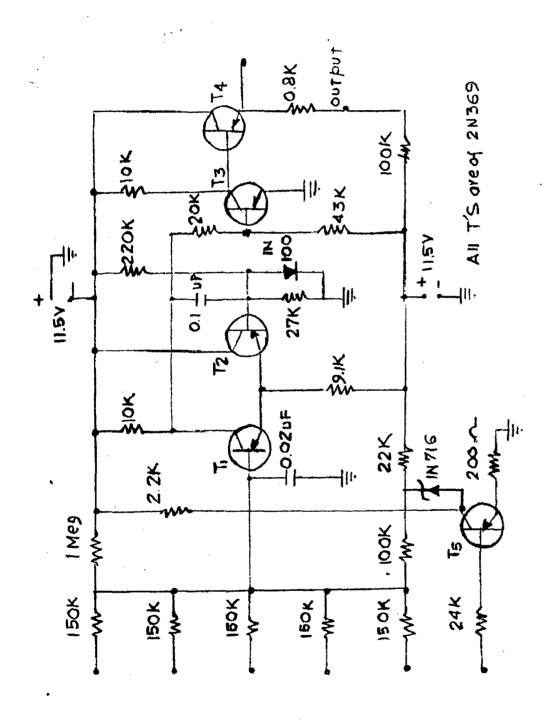


FIG 3.10 HARMON MODEL

the integrator and hold at at its initial value until the end of the pulse. Each pulse also increases the threshold by an amount VO and effecte decays with the constant T_2 . If T_2 is small compared to the normal intervals between pulses, it determines a relative refractory period in which a second pulse is readily elicited.

This model of French and Stein incorporate -

- t) Variable absolute & refractory period
- 2) Two time constant
- 3) Separate control of the accommodation to sub threshold voltage changes

3.12 A DENDRIFIC COMPAREMENT MODEL OF REUROM:

In this model [19] multiple input compartmental system analogous to a dendritic net is used. The model described a simulated action potential. The input to the model is voltage pulses and 0/P is simulated action potential.

A block diagram of the basic 5 compartment model is given in Figure 3.12. In this model FEP's are used. The simulated membrane potential as the trigger region is continuously complified compared to a reference potential. When this signal exceeds threshold, a Schmitt Trigger is fixed which in turn triggers a one-shot multivibrator. The O/P of the one-shot multi-vibrator is fed to both hyperpolarising and depolarising conductance wave from generators. The O/P voltages from these two wave shaping circuits are then applied to the gates of the hyperpolarising and depolarising FET's.

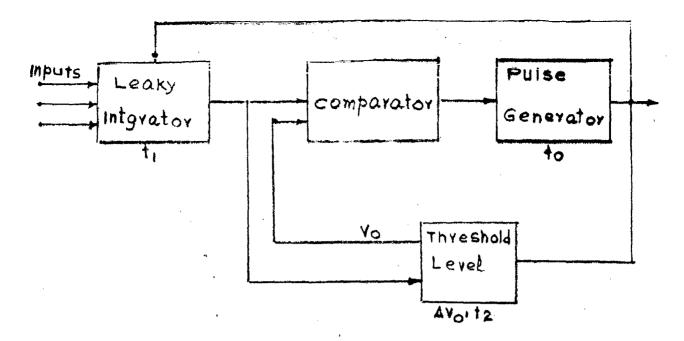
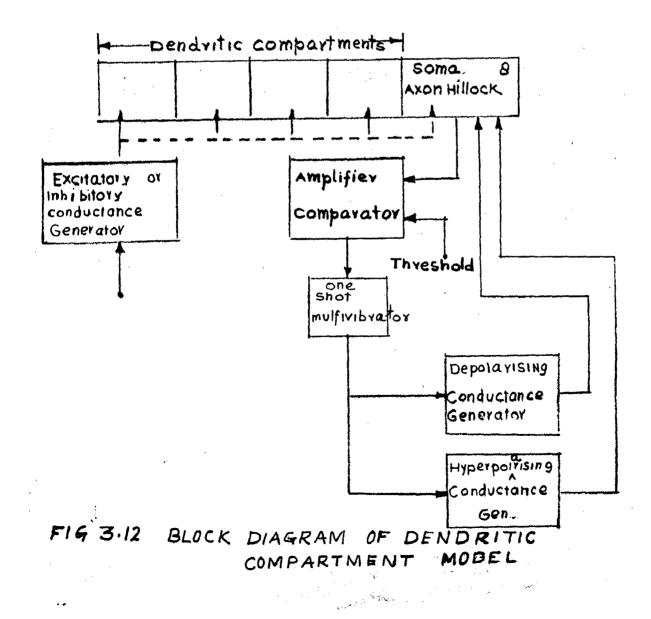


FIG.3.1 BLOCK DIAGRAM OF FRENCH & STEIN'S MODEL



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3.13 NODEL BY HACUNCE

It is simplified model of the Hodgkin-Huxley merve equation. The neuron model [23] proposed by Maguma is the circuit shown in Figure 3.13 where TD indicates a tunnel diode whole voltage-current characteristic (V Vs $F_{i}(V)$ is shown in Figure 3.14 and e (s) represents the voltage applied by the voltage pulse generator at time S.

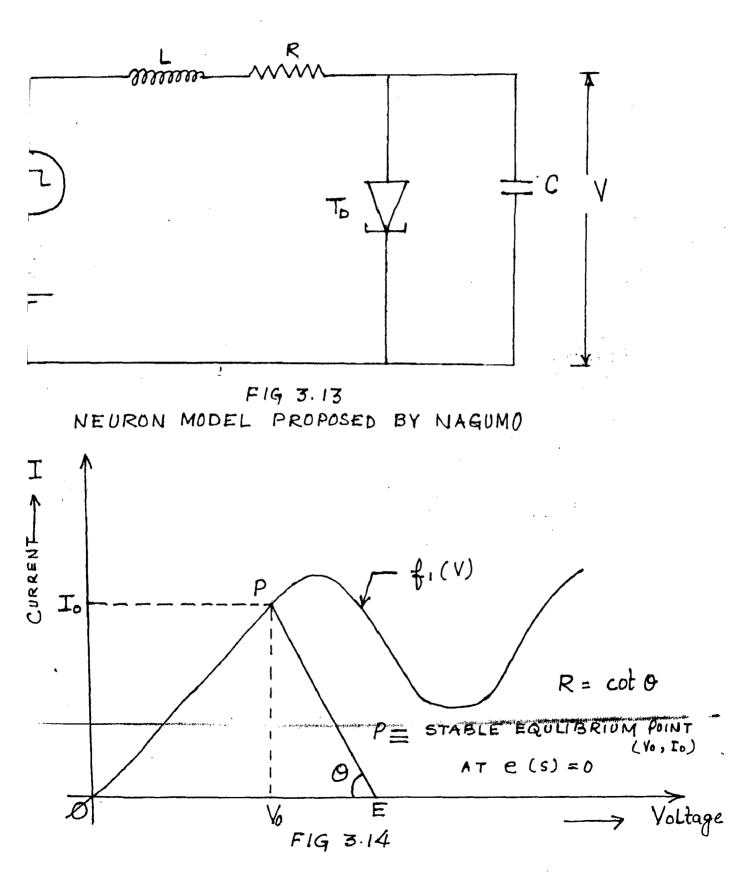
> The differential equation of the circuit was given by $\frac{dv}{ds} = -\frac{1}{6} (1 - f_1 (V))$ $\frac{dI}{ds} = -\frac{1}{5} (B + e(s) - V - BI)$

The response characteristic of an electric neuron model proposed by Magumo was theoretically investigated. In the degenerate case the behaviour of this neuron model is governed by a non-linear differential equation of the first order and two jump conditions. It was shown that the relation between the pulse width { or amplitude } of the stimulating pulse sequence with a fixed frequency and the firing rate of the nruon model takes the form of an extended contor function.

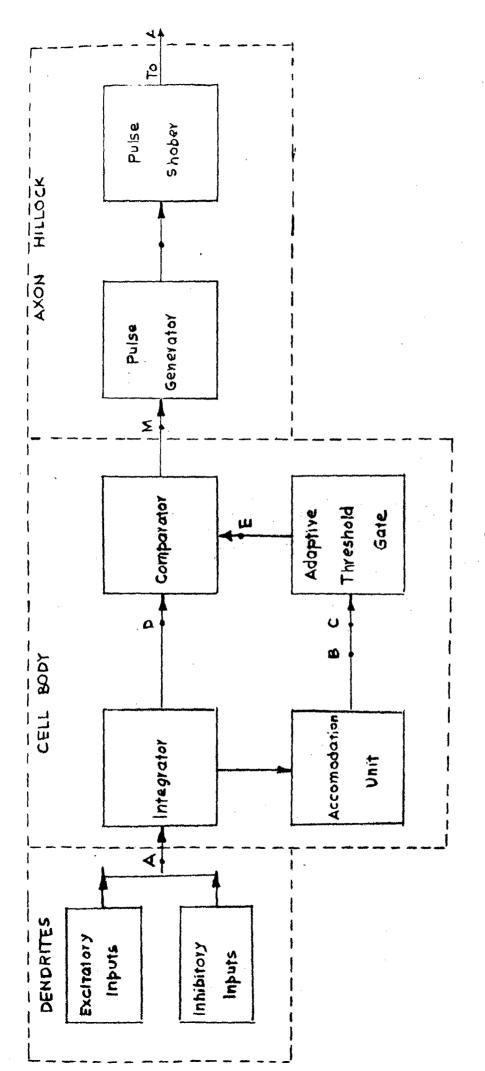
3.14 ELECTRONIC MODEL OF MEURON BY SAXENA:

In this model [34] proposed (Figure 3.15) the cell body of the neuron is represented by an integrator, the half wave rectifier, adaptive threshold gate and a comparator. The axonhillock is modelled by a monostable multi-vibrator, differentiator

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VOLTAGE - CURRENT CHARACTERSTIC





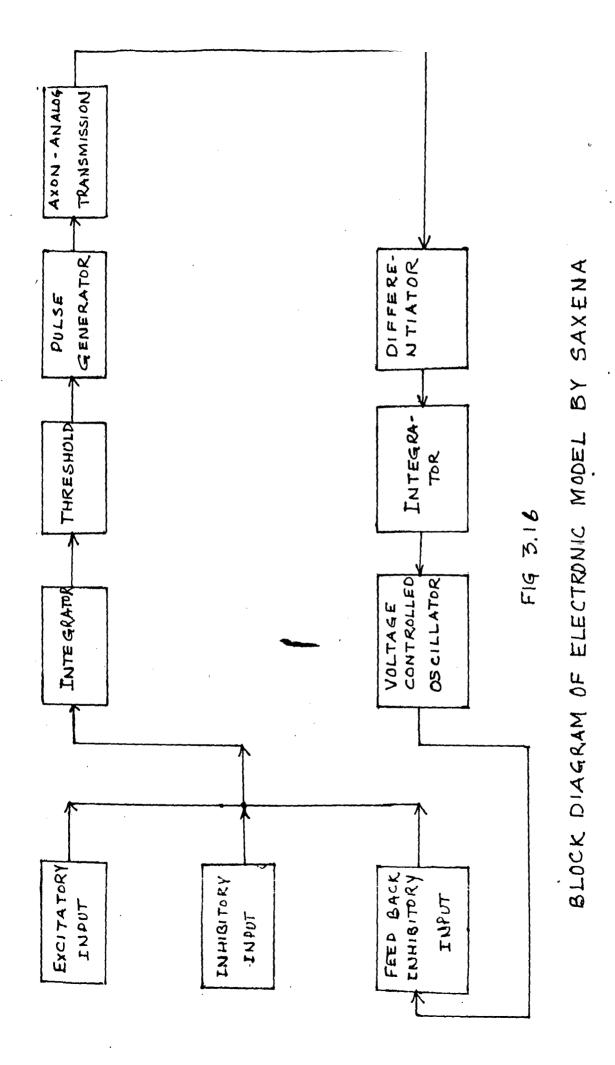
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and pulse-stretcher. The axon is represented by a resistance capacitance combinational transmission line. This axon analog line is triggered by a switch through mono-stable multivibrator and generates action potential which travels down along the line.

The time constant of the integrator represents the membrane time constant (= im3). The accommodation and adaptation phenomenon is simulated by half wave restifier and an adaptive threshold gate. The relative refractory period is decided by the time constant of the adaptive threshold gate. The O/P of the integrator and the adaptive threshold gate are compared by a comparator. The output of comparator is connected to a mono-stable multivibrator which triggers only when all the constant of the monostable multivibrator decides the absolute refractory period of neuron model. The output pulse of the multi-vibrator generates the action potential through differentiater and pulse shaper which travele down on the axon analog.

The model [26] proposed by Saxena simulates the transmission of information in the dendrites, cell body, anon hillock, anon and inhibitory feed back through Renshaw Cell. Remshaw Cell works as protective device against excessive excitation and generation of action potential. In this Model shown in Figure 3.16, most of the electrical characteristics of

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neurom along with its feed back loop through Renshaw Cell. The summation and integration of MPSP and IPSP inputs, integration phenomenom in cell body membrane, threshold and sub-threshold phenomenon, refractory period, inhibitory input from Renshaw Cell etc. can be easily studied by the bio-engineers. In this case threshold is taken arbitary value.

5.15 BIO-PHYSICAL MODEL TO EXPLAIN NERVE INPULSES:

The classical theory [24] of function in the nervous system posulates that the nerve impulse is the result of a sequential reversal as the membrane potential due to an increased permeability of the membrane, first to sadium ions, then to Potassium ions. The new theory presents a bio-physical model which depicts the nerve impulse as an event involving the motions of the electrons and waves, and their inter-actions with sodium and potassium atoms and ions. The velocity of themerve impulse (the most important parameter of the nerve function) is determined by the products of two constants : 0 - the speed of light, which is a constant for all nerves;

k = a constant for each nerve and is believed to be a specific property of nerve matter related in same way to the abomic process.

The theory proposes that ----

I. Function in the merve aron is dublistic; it involves three significant aspects; electrons and waves in motion and their interaction with atoms and ions.

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2. The dualistic nature accounts for the most fundamental characteristics of conduction of the nerve impulses

- a) <u>Periodicity</u>: Conduction of nerve impulse over long distances with constant velocity and form.
- b) <u>Hon-summing</u>: (two nerve impulses can not be the same at the same)time).
- c) <u>Quantum nature of each nerve</u>: The unit message of the nerve impulse is an indivisible unit.

The explanation for this offered by the classifical theory (the ironic hypothesis of nerve conduction) is that nerve exons have an 'absolute refractory period'. During this period a second nerve impulse can not be generated. According to new theory, the nerve impulse is an event during which two very different but inter-related phenomenon are not 'mixable' since one can not occur unless the other has completed its function. Thus, each component of the dualistic phenomenon remains discrete.

7. The velocity of the nerve impulse is dependent upon the product of the two constants: C, the universal constant - the speed of light and K, a product of two "Constants" factors: the speed of the atomic process, n_p , and the fibre configuration, t_g , as a rate constant.

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4. Function in the axon is regarded as being mathematical. The mathematics arise as a result of the fusion (inter-sotion, union, combinations) of energy and matter as depicted in the schematics and the quantum theoretical equations.

5. The notions of time, distance, velocity, etc. are formulated in symmptic region where "brain function" actually takes place. The exon is regarded mainly as a transporting system transporting numbers it receives from the symmptic region to another symmptic region. To correctly express this belief, it is postulated, there is a sympptic function, such that

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Where x is a constant number for every nerve impulse in a specific axon, the f is the synaptic function.

5. Therefore, the nerve impulse in the axon is regarded both as a wave and a number.

EXPERIMENTAL OBSERVATIONS ON VELCE THE THEORY IS BASED:

1. The resting membrane potential of various arone vary from 0.05 to 0.01 volts.

2. The nerve impulse is a two-time sequential reversal of the repeats

(a) From negative inside and positive outside, to positive inside and negative outside. This corresponds to the ascending limbs of the nerve impulse;

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(b) From positive inside and negative outside, to negative inside and positive outside. This corresponds to the descending limp of the nerve impulse and the restoration of the r-p-m-

3. The process described in (2) repeats itself excitaneously all along the axon with constant velocity and from regardless of its length.

4. Herve arons under constant conditions conduct a nerve impulse with a velocity and from that is specific and constant for that aron.

5. The velocity of the nerve impulse is an unayelinated nerve is approximately 1/10 of the velocity in myelinated nerve.

6. In a myelinated nerve, the resistance to current flow in nerve envelope (nerve membrane and myelin sheat) is so high, ions (sedium, potassium, chloride) cannot move across the nerve envelope. The current is made to flow between the gaps in the myelin sheath. These gaps are called the modes of Banwier. Thus, the nerve impulse is said to 'jump' from mode to node 'skipping' considerable sections of nerve, thus accounting for the higher velocities in myelinated nerves. This form of conduction in a myelinated nerve is called 'Saltatory Conduction'.

7. Conduction velocity is generally dependent upon fiber diameter. In mychinated merves the velocity also depends upon the thickness of the myclin sheath relative to agon diameter, and on the distance between modes (0.5 to 2.0mm) collectively, these parameters will be referred to in the theory as fiber geometry with the symbol (P_{μ}) .

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8. The mode of Ranvier - the distance between adjacent Schwann Galls is approximately 1 mioro meter (1x10⁻⁶ Heter). This is the only section of a myslinated nerve where the axon membrane is in free communication with the extra-cellular fluid. This section of the nerve the mode of Ranvier plys a most sritical rele in formation of the merve impulse, and in merve conduction because resting and action potentials are generated only at nodes, inter-model regions are unercitable.

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CHAPTER - 4

ELECTRONIC MODEL PROPOSED BI THE AUTHOR FOR NEURON FOR QUALITATIVE AWALTSIS

The author developed an electronic model of neuron which exhibits all electrical properties of actual neuron. This electronic model of memora has a local feed back path as is existing in actual system. This proposed model has following advantages over other models developed in the past.

- 1) The model is compact, reliable and inexpensive.
- ii) The physiological data has been handled with ressonable accuracy.
- iii) The model includes the local inhibitory feed back through Renshaw Cell as peported by Robert F. Schmidt [7].
- iv) The model includes the effects of temperature on neural excitability as reported by H.B. Maciwer and S.H. Rath [22].
- The model includes protective device Renshaw cells against excessive excitation and generation of action potential.
- vi) The model includes all the important electrical characteristics such as summation, all or none law, threshold, refractory period, etc. [34].
- vii) Linear IC's have been used to handle the physiological data of neuron for comvenience.

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viii) Resting potential in actual neuron is taken into consideration to decide threshold level.

Taking into consideration the above points, it is thought that the proposed model might be of use to understand and demonstrate the functions of the neuron.

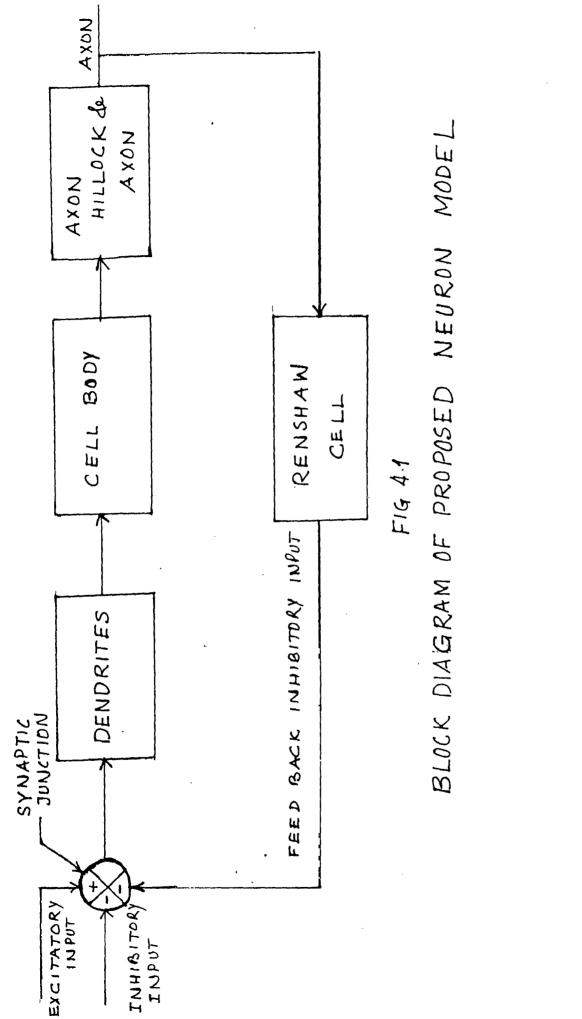
4.1 BLOCK DIAGRAM OF THE PROPOSED MODEL OF REVIEW:

The block diagram of the neuron model proposed by the author takes into considerations all the features of an actual neuron. The block diagram shown in Figure 4.1 shows the different blocks of the neuron model. The neuron and its feed back loop is divided into dendrites, cell body or some, axon hillock, axon or nerve fibre, and Remshaw Cell. Dendrites sense the information from adjoining cells at synaptic junctions and pass it on to cell body. In actual system number of dendrites can be as few as one and as many as thousands [2]. The cell body processes the information received from dendrites. The axon-hillock is the next section where action potential is initiated which finally travels down along axon. This output signal is feed back through Remshaw Cell.

The dendrites receiving excitatory, inhibitory inputs from other cells and an inhibitory input whose frequency depends upon the level of excitation from its axon through Renshaw Cell. The excitatory and inhibitory inputs of actual system are simulated in the form of positive and negative pulses by differentiating

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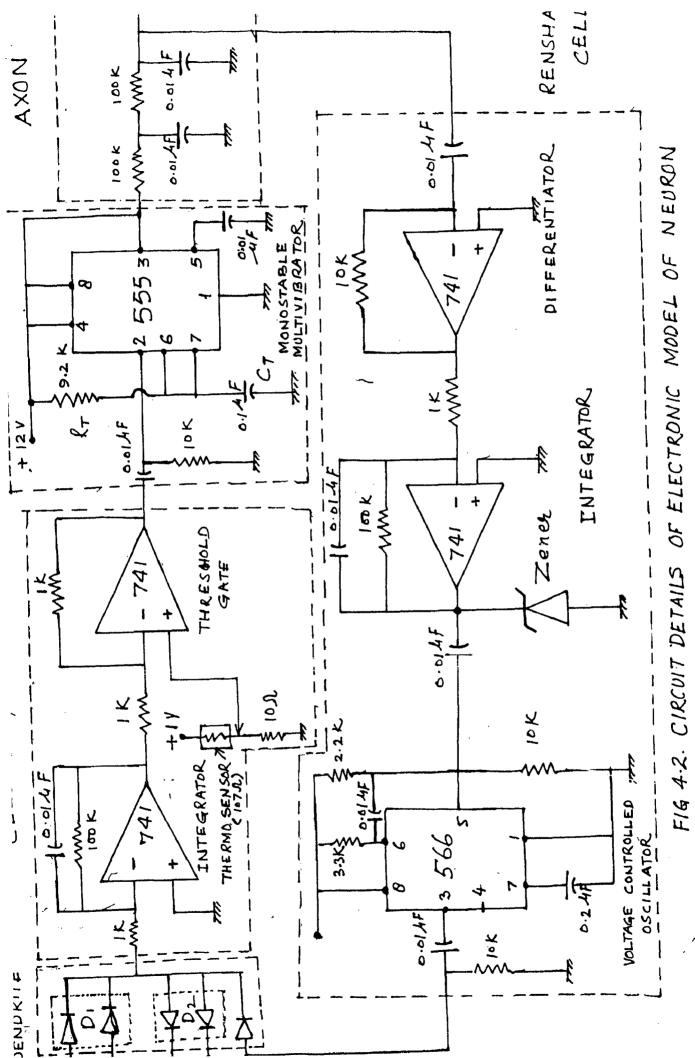
circuit. The frequency of pulses can be raised up to 500 Hz [2]. The call body representation consists of an integratory, threshold gate and temperature dependent threshold level. As the temperature changes the value of threshold changes because resting potential of the neuron changes as temperature changes in actual goten. The aron hillock is represented by a pulse generator (mono-stable multivibrator). The transmission line analogy is given to aron. The aron consists resistance - capacitance combinational transmission line. The Remaker Cell consists of wave shaping circuit and a voltage centralied cacillator. The mave shaping circuit further consists an differentiator and integrator. The output of the Remaker Cell is feed back to the cell body of the neuron. So it forms a local negative feed back loop with nearby neurons. In this way the Remaker Cells acts as protective device against excessive excitation.

The absolute refractory period is equal to the time period of the multivibrator (i.e. = 1 milli second) and the time constant of the integrator is equal to membrane time constant of cell body and is of the order of 1 milli second. The relative refractory period is decided by the time period of threshold gate.

4.2 DEFAILS OF ELECTRONIC MODEL OF MEURONS

The complete circuit details of the electronic model of the neuron is shown in Figure 4.2. There are two types of input are fed to the model one is excitatory input equivalent to EPSP

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and other is inhibitory imput equivalent to IPSP. The excitatory imput is given in the form of positive potential pulses and inhibitory inputs are in the form of negative potential pulses. Imput pulses are differentiated with the help of RC differentiator to get the sharp pulses. The diodes D_1 are used in the EPSP input allows only positive pulses. It blocks the negative pulses. Similarly diodes D_2 are used in IPSP input allows only negative pulses. It blocks positive pulses. That means that the same lime cannot be used for passing on both EPSP and IPSP input differentiating time constant of 1 milli second has been selected with C = 0.01 micro farade and H = 100 kbhm,

The length of dendrites i.e. the distance between synaptic junctions and the cell body is represented by a recistance. The larger value of resistance shows that the synaptic junction is for away from cell body and the smaller value of resistance indicates that the synaptic junction is very close to cell body. For this purpose a variable resistance of 100 kohm which can be adjusted as per the requirement is thought to be the acceptable representation.

The input of the Renshaw Cell and the EPSP and IPSP inputs are differentiated before applying at dendrites. All the inputs EPSP, IPSP and feed back through Renshaw Cell are connected to an integrator where integration of inputs takes place. The time constant of the ingrator which is decided by the parallel combination of resistance and capacitance is adjusted to be equal to actual membrane time constant. There are many experimental result available [2] to show the membrane time constant is of the

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order of i milli second. To provide the i milli second value of the membrane time constant a 100 kohm resistance and 0.01 micro farade capacitance has been used in this model. The other value of capacitance (i.e. 0.1 micro farade, 1.0 micro farade) may be used in the same model for getting the large value of membrane time constant for further study of neuron model. The output of +

The output of the integrator is given to the threshold for its comparison against the reference level. When the integrator output exceeds reference level (threshold) the threshold gate changes its state and provide a signal for further processing in the model. If theingrater output is below the reference level then threshold gives no response. This show the all or none law.

The threshold gate excite only when there is negative potential at the output of integrator i.e. the value of EPSP inputs are more than the value of IPSP inputs. If IPSP inputs value is more than HPSP's inputs value then the output at the integrator is positive and then threshold will not be crossed. Resting potential of about +80 mV [2] of a ctual neuron system provides for this reference. Thus the threshold gate has been designed to have reference of 480 mV. In this model the effects of temperature on the extitability of neuron as given by Maciver and Roth [22] has also been considered. For this purpose a thermosensor has been used so that its characteristic match with the requirement

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For this purpose a thermosensor of 107 OBN which exhibited the required obseractoristics is used. The resistance of thermosensor for different value of temperature is also shown in the Table-1.

For the working of electronic model, it is assumed that the resting nombrane potential of the neuron is -80mV at 19°C. This assumption is valid since this figure of -80mV has been found by many investigator. As the temperature changes to the 40°C the value of resting membrane potential changes from -80mV to -72mV. If the resting potential decreases to a value of -60mV then the action potential is generated even there is no input at that instant [2]. To get the above value of the resting potential we used a resistance of 10 ohm and a themmomensor of 109 ohm in the threshold gate circuit.

So as the temperature changes the resting membrane potential changes, so the threshold value changes. So the output of the threshold will not only depends on the input excitation signal put on temperature also. At high temperature the input signal of comparatively low amplitude can excite the threshold gate and generate a signal. This output signal of the threshold gate triggers the pulse generator which is a monostable multivibrator. The time period of the multi-vibrator is i milli second which is equal to the absolute refractory period.

In the present model, IC 555 is used as mono-stable multivibrator. The external timing depacttor $G_{\rm X}$ is held initially discharged. Upon application of a negative pulse to pin 2, the flipflop is set which releases the short circuit across the external

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espacitor. Now rise exponentially with the time constant $R_T C_T$, this time constant $R_T C_T$ is equivalent to the absolute formatory period. When the voltage across the expecter equal 2/3 Wos the threshold comparator rests the flipflop which in turn, discharge the capacites repidly and desired the output to its low state. The circuit triggers on a negative going input signal, when the level reaches 1/3 Wos. One-triggered the circuit will remain in this state until the set time is elapsed, even if it is triggered again during this interval. The time that the output is in high state Vs 1.1 $R_T C_T$. Applying a negative pulse simultimeously to reset terminal (Pin 4) and trigger terminal (Pin 2) during the timing cycle discharge the external depositor C_T and cause the cycle to start over again. The output pulse is square wave which can be get at (Pin 3).

The output generated by the monostable multivibrator travels down on resistance-capacitance analog of axon. As the length of axon increases the number of resistance-capacitance groups also increases. It is assumed as a long transmission line which is uniformly distributed over entire length. No action takes place in the axon-analog it only shows the elapse to transmit the signal in the axon.

These output pulses are transmitted to the central nervous system for further necessary control processing.

The shape of the output pulses are distorted due to the transmission of pulses slong the entire length of the axon analog

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which is the combination of resistance and capacitance. To over some this difficulty, the axon is connected to the differentiator unit whose output depends upon the number of action potential travelling along the axon not on the shape of action potential. For this purpose an operational amplifier IC 74t is used as a differentiator unit. The time constant of the differentiator unit is decided by the resistance and capacitance connected to its terminals and this is of the order of i milli second. With selecting the value of R = 100 K and C = 0.01 migrof. The output of the differentiator is a train of spikes. Fig 4.4

The differentiator output is connected to an integrator which integrates the train of spikes. The integrator controls the frequency of voltage controlled oscillator (VCO). The frequency of the output pulses of the integrator depends upon the time constant of the integrator which is decided by the remistance and capactionce commected to the operational amplifier IC 741. The time constant (RO) of the integrator is taken 1 milli second by choosing Rm100 K and Gm0.01 micronP. During the time constant RC if there is any spike arrives than it will not excite the integrator. So output of the integrator is a train of pulses of square pulses. Theim time of integration is i milli second.

The output of the integrator is connected to a voltage controller oscillator. In this electric circuit IC-566 is used as a voltage controlled oscillator. The SMC 566 function generator is a general purpose voltage controlled oscillator designed for

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highly limear frequency modullation. The control terminal (Pin 5) is biased externally with a voltage (Vc) in the range of

where Vec is the total supply voltage. The control voltage Ve is sent by the voltage divider formed with Rg and R_{3} . The modulating signal is then as coupled with the expacitor C_2 . The modulating signal can be directly connected as well; if the appropriate do bias voltage is applied to the control terminal. The frequency is given approximately by

$$P_{0} = \frac{2(V^{+} - V_{0})}{R_{1} Q_{1} V^{+}}$$

and R_{i} should be in the range 2 K R_{i} 20 K. A small capacitor typically 0.001 micronF should be connected between Fine 5 & 6 to eliminate possible oscillation in the control current source.

The output of VGO is connected as an inhibitory imput to dendrites through a differentiator i.e. a combination af Resistance and Capacitance. The VGO output increase with increase in excitation. So this nots as protection device against excessive excitation. As the excitation increase from a certain level the imput of the VGO is also large. So subput of VGO also impresse proportionately but WGO output is connected as inhibitory input to dendrites, it decrease the summing of all WSP and IPSPs inputs. So far high excitation the output at the axon is not effected to much so the signal transmitted to the CHS is of regularized nature. The impress of the output frequency of VGO ultimately decreased the excitation input of neuron.

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4.3 <u>RIPERIMENTAL RESULTS</u>:

The electronic model of neuron proposed by the author was fabricated and has been tested for its various characteristics and processes. It shows all the electrical characteristics of neuron.

1. There is a particular threshold value for an input below which there is no excitation (there is no output). All the threshold or above threshold input the neural system is excited and output is observed and action potential generated. Output aplitude response for different values of the stap input for different values of threshold is shown in Table-1.

Threshold value = 1 V		Threshold value = 2V		Threshold value-37	
Input	Output	Input	Output	Input	Output
0+0	NIL	Q	BIL	0	NIL
0.5	BLL	0.5	HIL	0.5	NIL
1.0	XIL	1.0	NIL	1.0	MIL
1.5	10	1.5	WIL	1.5	NIL
2.0	10	2.0	NIL	2.0	NIL
4.0	10	2.5	10	2.5	NIL
5.0	10	3.0	10	3.0	MIL
		4.0	10	4.0	10
		5.0	10	5.0	10

Table-1

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2. (11) The different values of the PPSP and IPSP inputs are applied as input to the proposed model. The action potential is generated only when the sum of the EPSPs and IPSPs inputs is above threshold level.

5. When a pulse of constant amplitude above the threshold level and variable frequency is applied at the input of themeurons; the output signal is observed only for the time which satisfies the condition for absolute refractory period. When the frequency exceeds the limit, the output action potential is absent. In the proposed model the absolute refractory period is i milli second i.e. equal to the time constant of the monostable multivibrator.

The frequency range of neuron model and therefore the model becomes slow. This is similar to an actual neuron. Table-2 shows the frequency response for the absolute refractory period of 1 milli second.

Input Pulse Prequency	Output Response		
50	Present		
100	Present		
\$50	Present		
200	Present		
250	Propent		
300	Present		
350	Present		
400 .	Present		
450	Present		
500	Absent		
550	Absent		
600	Abaent		

Tablen2

(v) The output frequency response of the neuron model is shown in Figure 4.3 for the several values of the input signal, which is a steady state d.q. woltage, when they are applied just before the multi-vibrator. It is within the range as in the actual neuron.

5. When the sum of EPSPs and IPSPs inputs are less than the threshold value then there is no action potential generated and when the sum is more than threshold level then action potential is generated. Above threshold level it does not depend upon the amplitude of the input. So it show all or none law. As in the actual neuron i.e. for sub-threshold stimulus produces no excitation, while threshold and above threshold produces excitation as shown in Table-1.

6. In the present work the effect of temperature is also considered. A thepmo-sensor is used in the threshold level-gate. As the temperature increases threshold level decreases, so the threshold gate triggered at sub-threshold level.

7. The membrane resting potential is used for threshold level, which changes as the temperature changes, As temperature increase resting membrane potential increases so the threshold level decreases.

8.

The waveshapes at different terminal are shown in FIG 4.4.

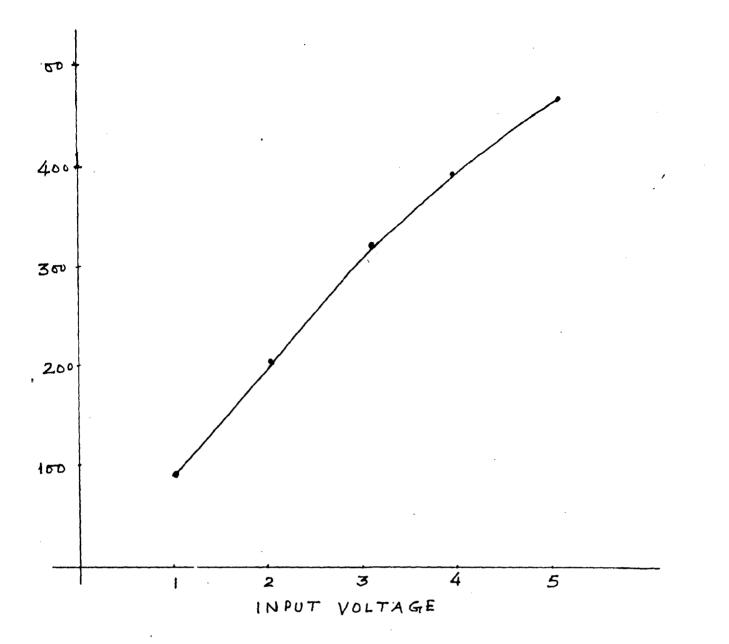
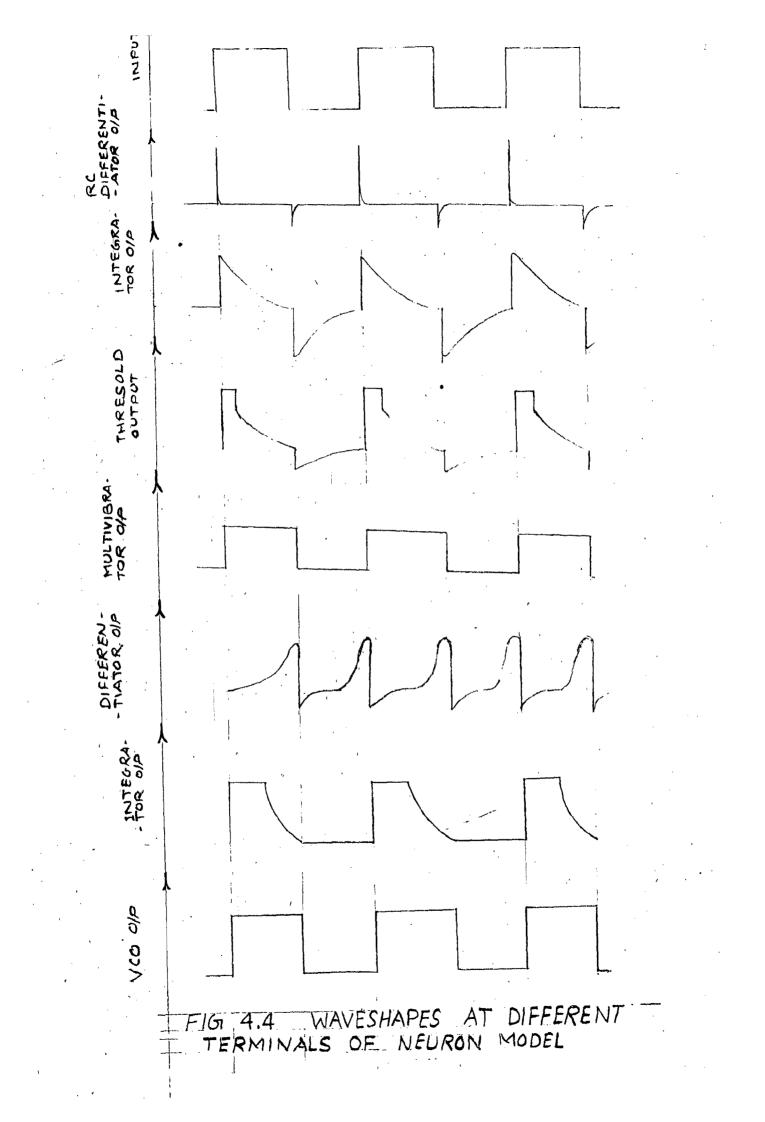


FIG 4.3 OUTPUT FREQUENCY V/S INPUT VOLTAGE



The model proposed by the author shows all the electrical properties of an actual neurom. The experimental results observed are similar to the results which have been observed by the many bio-engineers and scientist in past.

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CHAPTER - 5

CONCLUSION AND DISCUSSION.

The dissertation deals with an electronic model of neuron processes and its feed back loop through Renshaw Cell. It simulates the transmission of information in the dendrites, cell body, aron Hillock, aron and inhibitory feed back through Renshaw Cell. Renehaw Cell works as protective device against excessive excitation and generation of action potential. The existing models are reviewed in the present work.

The model described in this dissertion includes most of the electrical characteristics of neuron. The effect of the temperature on the resting membrane potential which acts as the threshold of the proposed neurla model is also taken into account. The summation and integration of EPSPs and IPSPs inputs, integration phenomenon in cell body membrane, threshold and sub-threshold phenomenon, refractory period, inhibitory input from Remshaw cell etc. can be easily studied by the bio-engineers and neurophysiologists for explaining the neuron processes. The model is compact, reliable and inexperience and several such models can be inter-connected to study the behaviour of inter-neurons, merve cent-res and other complex processes. It also proves to be a good eid to diagnostic and prosthetic purposes. If it becomes possible to construct a very small micro-structure model than it may be helpful in treatment of some paralysis cases, where a small segment has stopped working. by replacing it with artificial built micro-structure model of neuron.

This model has the advantage that it is very flexible in its principal of operation and studies can be carried out on the properties of different kinds of nerve cells by the simple process of changing several parameters of the circuit. Integrated circuit chips have been used in the present model so as to mineturize the set up.

The above model could be perfected by including gradually discovered physiological aspects of the neural structure. REFERENCES

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